

Global United Technology Services Co., Ltd.

Report No.: GTS201705000091F01

FCC Report (LTE)

Applicant: Positioning Universal Inc

Address of Applicant: 4660 La Jolla Village Drive Suite 1100, San Diego, CA 92122,

United States

Manufacturer: Fujiao Communications

Address of 1802 room, zhongshanwest road 2368, xuhui district,

Shanghai, China Manufacturer:

Equipment Under Test (EUT)

Product Name: **GPS Tracker**

Model No.: **FJ1000LT**

FCC ID: 2AHRH-FJ1000LT

Applicable standards: FCC CFR Title 47 Part 2: 2016

> FCC CFR Title 47 Part 24: 2016 FCC CFR Title 47 Part 27: 2016

May 17, 2017 Date of sample receipt:

May 18-31, 2017 **Date of Test:**

June 01, 2017 Date of report issued:

PASS * **Test Result:**

In the configuration tested, the EUT complied with the standards specified above.

Authorized Signature:

Robinson Lo Laboratory Manager

This results shown in this test report refer only to the sample(s) tested, this test report cannot be reproduced, except in full, without prior written permission of the company. The report would be invalid without specific stamp of test institute and the signatures of compiler and approver.



1 Version

Version No.	Date	Description
00	June 01, 2017	Original

Prepared By:	Tiger. Char	Date:	June 01, 2017	
	Project Engineer			
Check By:	Andy wa	Date:	June 01, 2017	
	Reviewer			



2 Contents

			Page
C	OVER F	PAGE	1
1	VER	SION	2
2	CON	ITENTS	3
3	TES	T SUMMARY	4
4		IERAL INFORMATION	
	4.1	GENERAL DESCRIPTION OF EUT	
	4.2	RELATED SUBMITTAL(S) / GRANT (S)	
	4.3	TEST METHODOLOGY	
	4.4	TEST FACILITY	6
	4.5	TEST LOCATION	6
5	TES	T INSTRUMENTS LIST	7
6	SYS	TEM TEST CONFIGURATION	8
	6.1	Test mode	8
	6.2	CONFIGURATION OF TESTED SYSTEM	
	6.3	CONDUCTED PEAK OUTPUT POWER	10
	6.4	OCCUPY BANDWIDTH	
	6.5	MODULATION CHARACTERISTIC	
	6.6	OUT OF BAND EMISSION AT ANTENNA TERMINALS	
	6.7	ERP, EIRP MEASUREMENT	
	6.8	FIELD STRENGTH OF SPURIOUS RADIATION MEASUREMENT	
	6.9	FREQUENCY STABILITY V.S. TEMPERATURE MEASUREMENT	
	6.10	FREQUENCY STABILITY V.S. VOLTAGE MEASUREMENT	
7	TES	T SETUP PHOTO	91
0	ELIT	CONSTRUCTIONAL DETAILS	0.2



3 Test Summary

Test Item	Section in CFR 47	Result	
DE Everagues (CAD)	Part 1.1307	D*	
RF Exposure (SAR)	Part 2.1093	Pass*	
	Part 2.1046		
RF Output Power	Part 24.232 (c)	Pass	
	Part 27.50(c)(10)/(d)(4)		
Modulation Characteristics	Part 2.1047	N/A	
	Part 2.1049		
99% & -26 dB Occupied Bandwidth	Part 24.238	Pass	
	Part 27.53(h)/(g)		
	Part 2.1051		
Spurious Emissions at Antenna Terminal	Part 24.238 (a)	Pass	
	Part 27.53(h)/(g)		
	Part 2.1053		
Field Strength of Spurious Radiation	Part 24.238 (a)	Pass	
	Part 27.53(h)/(g)		
Out of hand emission, Rand Edge	Part 24.238 (a)	Page	
Out of band emission, Band Edge	Part 27.53(h)/(g)	Pass	
Frequency stability vs. temperature	Part 2.1055(a)(1)(b)	Pass	
Frequency stability vs. voltage	Part 2.1055(d)(1)(2)	Pass	

Pass: The EUT complies with the essential requirements in the standard.

N/A: Not applicable.



4 General Information

4.1 General Description of EUT

Product Name:	GPS Tracker
Model No.:	FJ1000LT
Hardware Version:	P1.0
Software Version:	LR4.3.4.1-29555
Support Networks:	LTE
Support Bands:	LTE Band 2, LTE Band 4, LTE Band 12
Channel Bandwidth:	LTE Band 2: 5MHz; 10MHz; 15MHz; 20MHz
	LTE Band 4: 5MHz; 10MHz; 15MHz; 20MHz
	LTE Band 12: 5MHz; 10MHz
TX Frequency:	LTE Band 2: 1850.70MHz-1909.30MHz
	LTE Band 4: 1710.70MHz-1754.30MHz
	LTE Band 12: 698.70MHz-715.30MHz
Modulation type:	LTE Band 2/4/12: QPSK, 16QAM
Antenna type:	Integral antenna
Antenna gain:	1.51dBi(Band 2), 1.42dBi(Band 4), 1.23dBi(Band 12)
Power supply:	DC 12V



4.2 Related Submittal(s) / Grant (s)

This submittal(s) (test report) is filing to comply with Section Part 27 of the FCC CFR 47 Rules.

4.3 Test Methodology

Both conducted and radiated testing were performed according to the procedures document on TIA/EIA 603 and FCC CFR 47.1046, 2.1047, 2.1049, 2.1051, 2.1053, 2.1055 and 2.1057

4.4 Test Facility

The test facility is recognized, certified, or accredited by the following organizations:

• FCC —Registration No.: 600491

Global United Technology Services Co., Ltd., Shenzhen EMC Laboratory has been registered and fully described in a report filed with the (FCC) Federal Communications Commission. The acceptance letter from the FCC is maintained in files. Registration 600491, June 22, 2016.

• Industry Canada (IC) —Registration No.: 9079A-2

The 3m Semi-anechoic chamber of Global United Technology Services Co., Ltd. has been registered by Certification and Engineering Bureau of Industry Canada for radio equipment testing with Registration No.: 9079A-2, August 15, 2016.

4.5 Test Location

All tests were performed at:

Global United Technology Services Co., Ltd.

Address: No. 301-309, 3/F., Jinyuan Business Building, No.2, Laodong Industrial Zone, Xixiang Road, Baoan District, Shenzhen, Guangdong, China 518102

Tel: 0755-27798480 Fax: 0755-27798960



5 Test Instruments list

Rad	Radiated Emission:								
Item	Test Equipment	Manufacturer	Model No.	Inventory No.	Cal.Date (mm-dd-yy)	Cal.Due date (mm-dd-yy)			
1	3m Semi- Anechoic Chamber	ZhongYu Electron	9.0(L)*6.0(W)* 6.0(H)	GTS250	July. 03 2015	July. 02 2020			
2	Control Room	ZhongYu Electron	6.2(L)*2.5(W)* 2.4(H)	GTS251	N/A	N/A			
3	Spectrum Analyzer	Agilent	E4440A	GTS533	Jun. 29 2016	Jun. 28 2017			
4	EMI Test Receiver	Rohde & Schwarz	ESU26	GTS203	Jun. 29 2016	Jun. 28 2017			
5	BiConiLog Antenna	SCHWARZBECK MESS-ELEKTRONIK	VULB9163	GTS214	Jun. 29 2016	Jun. 28 2017			
6	Double -ridged waveguide horn	SCHWARZBECK MESS-ELEKTRONIK	9120D-829	GTS208	Jun. 25 2016	Jun. 24 2017			
7	Horn Antenna	ETS-LINDGREN	-LINDGREN 3160 GTS21		Mar. 25 2017	Mar. 24 2018			
8	EMI Test Software	AUDIX	E3	N/A	N/A	N/A			
9	Coaxial Cable	GTS	N/A	GTS213	Mar. 25 2017	Mar. 24 2018			
10	Coaxial Cable	GTS	N/A	GTS211	Mar. 25 2017	Mar. 24 2018			
11	Coaxial cable	GTS	N/A	GTS210	Mar. 25 2017	Mar. 24 2018			
12	Coaxial Cable	GTS	N/A	GTS212	Mar. 25 2017	Mar. 24 2018			
13	Amplifier(100kHz-3GHz)	HP	8347A	GTS204	Jun. 29 2016	Jun. 28 2017			
14	Amplifier(2GHz-20GHz)	HP	8349B	GTS206	Jun. 29 2016	Jun. 28 2017			
15	Amplifier (18-26GHz)	Rohde & Schwarz	AFS33-18002 650-30-8P-44	GTS218	Jun. 25 2016	Jun. 24 2017			
16	Band filter	Amindeon	82346	GTS219	Mar. 25 2017	Mar. 24 2018			
17	Universal Radio Communication tester	ROHDE&SCHWARZ	CMU 200	GTS538	June. 29 2016	June. 28 2017			
18	Wideband Radio Communication Tester	ROHDE&SCHWARZ	CMW 500	GTS539	June. 29 2016	June. 28 2017			

Gen	General used equipment:								
Item	Test Equipment	Manufacturer	Model No.	Inventory No.	Cal.Date (mm-dd-yy)	Cal.Due date (mm-dd-yy)			
1	Barometer	ChangChun	DYM3	GTS257	July 06 2016	July 05 2017			



6 System test configuration

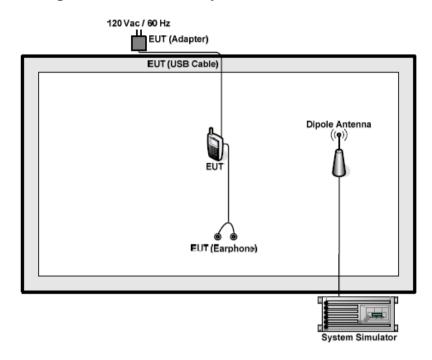
6.1 Test mode

During all testing, EUT is in link mode with base station emulator at maximum power level. The spurious emission measurements were carried out in semi-anechoic chamber with 3-meter test range, and EUT is rotated on three test planes to find out the worst emission.

Test modes								
rest modes								
Band Radiated Conducted								
LTE Band 2	■ QPSK and 16QAM link	■ QPSK and 16QAM link						
LTE Band 4 ■ QPSK and 16QAM link ■ QPSK and 16QAM link								
LTE Band 12	■ QPSK and 16QAM link	■ QPSK and 16QAM link						



6.2 Configuration of Tested System





6.3 Conducted Peak Output Power

Test Requirement:	Part 24.232 (c); Part 27.50(c)(10)/(d)(4)				
Test Method:	FCC part2.1046				
Limit:	LTE Band 2: 2W				
	LTE Band 4: 1W				
	LTE Band 12: 3W				
Test setup:	EUT Splitter Communication Tester Power meter				
	Note: Measurement setup for testing on Antenna connector				
Test Procedure:	The transmitter output port was connected to base station.				
	The RF output of EUT was connected to the power meter by RF cable and attenuator, the path loss was compensated to the results for each measurement.				
	Set EUT at maximum power through base station.				
	Select lowest, middle, and highest channels for each band and different modulation.				
	5. Measure the maximum burst average power.				
Test Instruments:	Refer to section 6.0 for details				
Test mode:	Refer to section 6.1 for details				
Test results:	Pass				



Measurement Data

	Band 2							
				Act	ual output power(di	3m)		
Bandwidth	Mode	RB Size	RB Offset	Channel 18625 1852.5MHz	Channel 18900 1880.0MHz	Channel 19175 1907.5MHz		
		1	0	21.53	21.51	21.30		
		1	13	21.86	22.89	20.03		
		1	24	21.91	21.33	20.86		
	QPSK	12	0	20.00	22.83	21.17		
		12	6	20.08	21.19	20.33		
		12	13	22.59	21.28	20.68		
5MHz		25	0	20.82	20.35	22.91		
SIVITZ		1	0	21.79	21.52	21.32		
		1	13	20.26	22.95	21.95		
		1	24	20.55	22.97	22.96		
	16QAM	12	0	20.33	21.24	21.91		
		12	6	22.58	22.68	22.88		
		12	13	21.05	21.58	22.87		
		25	0	21.67	21.74	20.37		
				Act	ual output power(di	3m)		
Bandwidth	Mode	RB Size	RB Offset	Channel 18650 1855.0MHz	Channel 18900 1880.0MHz	Channel 19150 1905.0MHz		
		1	0	20.93	21.98	22.32		
		1	25	20.09	21.80	22.46		
		1	49	21.29	22.45	21.33		
10MHz	QPSK	25	0	21.10	22.80	21.50		
		25	13	22.24	21.49	21.76		
		25	25	21.33	22.99	21.59		
		50	0	22.73	20.13	20.40		
				Act	ual output power(dl	3m)		
Bandwidth	Mode	RB Size	RB Offset	Channel 18675 1857.5MHz	Channel 18900 1880.0MHz	Channel 19125 1902.5MHz		
	_	1	0	21.16	21.60	20.24		
		1	38	21.94	21.40	22.00		
		1	74	22.50	22.98	21.42		
15MHz	QPSK	36	0	21.42	20.27	21.83		
		36	18	22.31	20.32	21.38		
		36	39	22.77	22.95	21.96		
		75	0	20.71	22.36	20.43		



				Act	ual output power(di	3m)
Bandwidth	Mode	RB Size	RB Offset	Channel 18700 1860.0MHz	Channel 18900 1880.0MHz	Channel 19100 1900.0MHz
		1	0	22.83	20.60	21.90
		1	50	20.97	21.79	21.34
		1	99	22.00	22.66	21.46
20MHz	QPSK	50	0	20.49	21.48	21.76
		50	25	20.15	22.04	20.25
		50	50	22.45	20.98	22.78
		100	0	20.74	22.66	20.79
	1		B	and 4		
				Act	ual output power(dl	3m)
Bandwidth	Mode	RB Size	RB Offset	Channel 19975 1712.5MHz	Channel 20175 1732.5MHz	Channel 20375 1752.5MHz
		1	0	20.13	22.43	20.90
		1	13	21.02	22.45	22.08
	QPSK	1	24	20.72	22.22	20.24
		12	0	22.95	22.77	22.48
		12	6	20.82	20.29	22.68
		12	13	21.11	22.76	21.39
55.41.1		25	0	20.68	20.16	22.83
5MHz	16QAM	1	0	22.44	21.21	20.10
		1	13	21.18	20.46	20.83
		1	24	21.38	22.92	20.43
		12	0	22.65	22.39	22.66
		12	6	21.01	20.69	20.76
		12	13	22.87	22.60	20.62
		25	0	21.60	20.91	21.86
				Act	ual output power(dl	3m)
Bandwidth	Mode	RB Size	RB Offset	Channel 20000 1715.0MHz	Channel 20175 1732.5MHz	Channel 20350 1750.0MHz
		1	0	22.31	22.07	21.84
		1	25	22.12	22.02	21.02
		1	49	20.37	20.61	20.19
10MHz	QPSK	25	0	20.18	21.17	20.30
		25	13	21.61	22.86	20.29
		25	25	22.00	20.49	21.59
		50	0	20.72	22.00	22.84



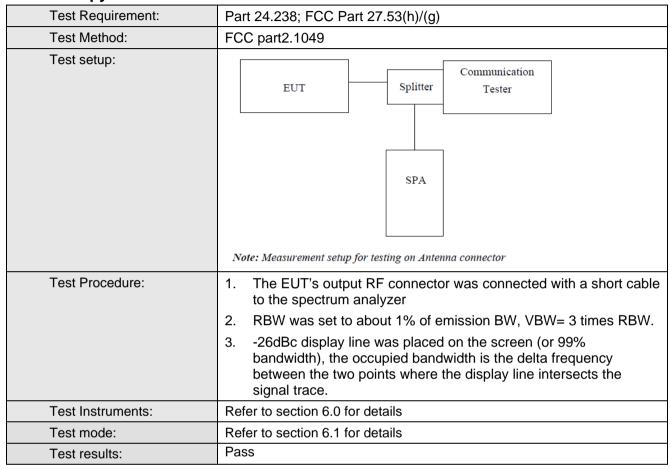
				Act	ual output power(di	3m)
Bandwidth	Mode	RB Size	RB Offset	Channel 20025 1717.5MHz	Channel 20175 1732.5MHz	Channel 20325 1747.5MHz
		1	0	22.35	22.14	22.88
		1	38	21.65	22.84	21.95
		1	74	20.85	21.82	21.90
15MHz	QPSK	36	0	22.11	21.93	20.98
-		36	18	21.61	20.72	20.20
		36	39	21.59	21.32	22.84
		75	0	21.33	21.49	22.51
				Act	ual output power(dl	3m)
Bandwidth	Mode	RB Size	RB Offset	Channel 20050 1720.0MHz	Channel 20175 1732.5MHz	Channel 20300 1745.0MHz
		1	0	22.89	20.94	22.10
		1	50	20.27	21.82	22.27
		1	99	22.90	21.34	20.38
20MHz	QPSK	50	0	21.48	20.76	22.72
		50	25	22.80	21.47	22.25
		50	50	21.73	21.08	21.12
		100	0	20.43	22.42	21.22
			Ва	nd 12		
				Act	ual output power(di	3m)
Bandwidth	Mode	RB Size	RB Offset	Channel 23025 700.5MHz	Channel 23095 707MHz	Channel 23155 713.5MHz
		1	0	22.65	22.49	21.74
		1	13	20.80	20.92	20.30
		1	24	20.82	20.98	22.09
	QPSK	12	0	21.17	22.99	21.44
		12	6	22.30	20.34	22.93
		12	13	20.67	21.09	21.57
5 N AL I -		25	0	20.10	22.09	20.73
5MHz		1	0	20.99	20.77	21.99
		1	13	21.50	22.68	22.32
		1	24	22.31	22.54	20.54
	16QAM	12	0	20.87	20.25	20.95
		12	6	22.08	20.18	21.43
		12	13	22.85	22.81	22.32
		25	0	21.05	21.90	21.65



Bandwidth	Mode	RB Size	RB Offset	Actual output power(dBm)			
				Channel 23050 703.0MHz	Channel 23095 707MHz	Channel 23130 711.0MHz	
10MHz	QPSK	1	0	22.62	22.90	20.92	
		1	25	20.95	21.18	21.40	
		1	49	20.84	22.12	20.38	
		25	0	22.54	20.33	20.35	
		25	13	21.01	20.11	22.60	
		25	25	21.75	20.32	20.95	
		50	0	21.67	22.72	21.60	



6.4 Occupy Bandwidth





Measurement Data

QPSK mode:

QPSK mode:	Channel	Channel	RB Configure		99% Occupy	-26dB
EUT Mode	Bandwidth		RB Size	RB Offset	bandwidth (KHz)	bandwidth (KHz)
		Low range	25	0	4537.70	5720.00
	5MHz	Mid range	25	0	4548.30	5945.00
		High range	25	0	4549.90	5727.00
	10MHz	Low range	50	0	8977.70	10783.00
		Mid range	50	0	8951.10	10378.00
LTE Band 2		High range	50	0	8942.00	10359.00
LIE Banu 2		Low range	75	0	13513.70	16080.00
	15MHz	Mid range	75	0	13487.40	16415.00
		High range	75	0	13441.10	16001.00
		Low range	100	0	18001.30	20530.00
	20MHz	Mid range	100	0	17951.40	20250.00
		High range	100	0	17943.40	20439.00
FUT Made	Channel Bandwidth	Channel	RB Configure		99% Occupy	-26dB
EUT Mode			RB Size	RB Offset	bandwidth (KHz)	bandwidth (KHz)
	5MHz	Low range	25	0	4539.30	5787.00
		Mid range	25	0	4536.20	5702.00
		High range	25	0	4555.50	5809.00
	10MHz	Low range	50	0	8971.20	10628.00
		Mid range	50	0	8969.20	10368.00
LTE Band 4		High range	50	0	8938.10	10787.00
LIE Ballu 4	15MHz	Low range	75	0	13549.10	16225.00
		Mid range	75	0	13482.90	16251.00
		High range	75	0	13495.40	16299.00
		Low range	100	0	17979.30	20624.00
	20MHz	Mid range	100	0	17987.10	20582.00
		High range	100	0	17977.80	20635.00
EUT Mode	Channel Bandwidth	Channel	RB Configure		99% Occupy bandwidth	-26dB bandwidth
EUT MOUE			RB Size	RB Offset	(KHz)	(KHz)
LTE Band 12	5MHz	Low range	25	0	4537.90	5829.00
		Mid range	25	0	4529.80	5747.00
		High range	25	0	4517.10	5632.00
		Low range	50	0	8979.90	10437.00
	10MHz	Mid range	50	0	8975.20	10724.00
		High range	50	0	8924.70	10437.00



16QAM mode:

EUT Mode	Channel	Channel	RB Co	onfigure	99% Occupy bandwidth (KHz)	-26dB bandwidth (KHz)
EOT Wode	Bandwidth		RB Size	RB Offset		
LTE Band 2	5MHz	Low range	25	0	4550.40	5990.00
		Mid range	25	0	4554.50	5894.00
		High range	25	0	4556.60	5957.00
EUT Mode	Channel Bandwidth	Channel	RB Co	onfigure	99% Occupy bandwidth (KHz)	-26dB bandwidth (KHz)
			RB Size	RB Offset		
LTE Band 4	5MHz	Low range	25	0	4549.30	5937.00
		Mid range	25	0	4535.10	5831.00
		High range	25	0	4542.30	5633.00
ELIT Manda	Channel Bandwidth	Channel	RB Configure		99% Occupy	-26dB
EUT Mode			RB Size	RB Offset	bandwidth (KHz)	bandwidth (KHz)
LTE Band 12	5MHz	Low range	25	0	4512.20	5845.00
		Mid range	25	0	4548.70	5908.00
		High range	25	0	4491.50	5869.00

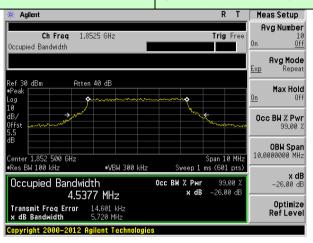


Test plot as follows:

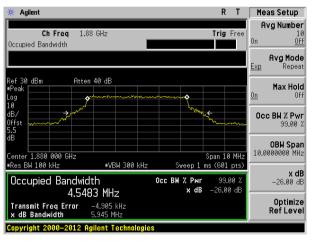
QPSK mode:

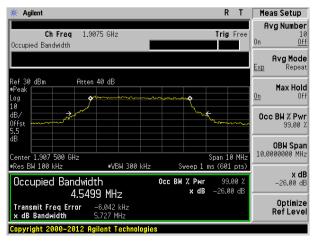
Test band: LTE Band 2

Channel Bandwidth: 5MHz



Lowest channel



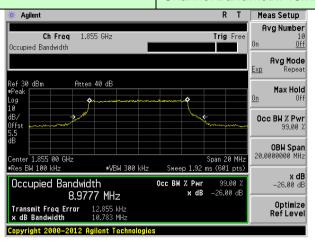


Highest channel

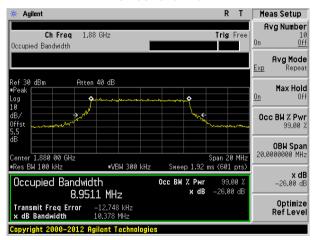


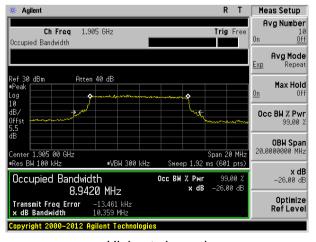
Test band: LTE Band 2

Channel Bandwidth: 10MHz



Lowest channel



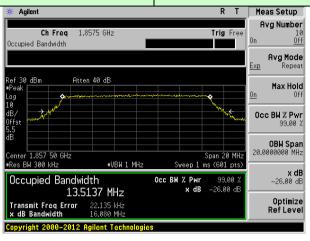


Highest channel

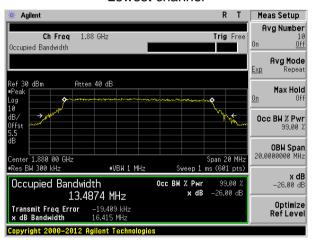


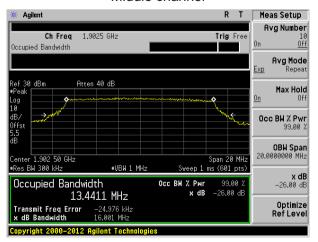
Test band: LTE Band 2

Channel Bandwidth: 15MHz



Lowest channel



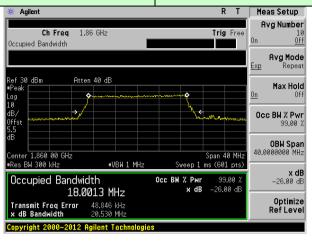


Highest channel

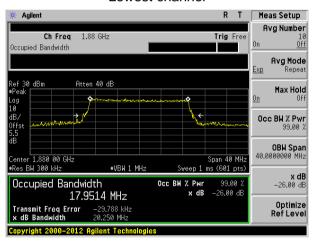


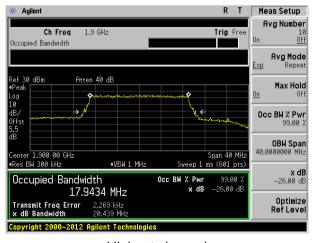
Test band: LTE Band 2

Channel Bandwidth: 20MHz



Lowest channel



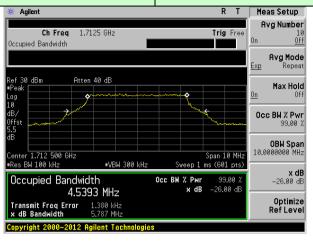


Highest channel

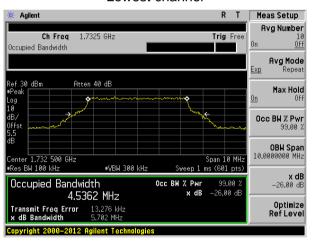


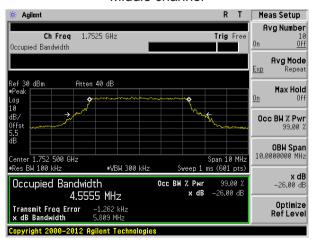
Test band: LTE Band 4

Channel Bandwidth: 5MHz



Lowest channel



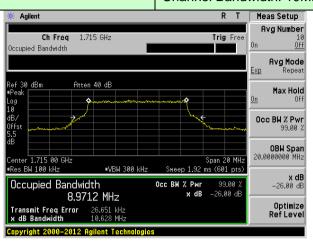


Highest channel

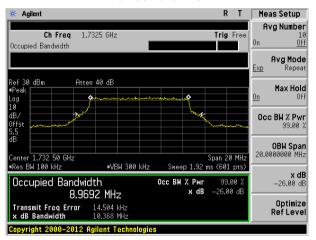


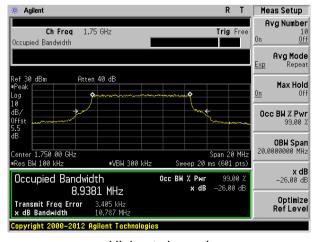
Test band: LTE Band 4

Channel Bandwidth: 10MHz



Lowest channel



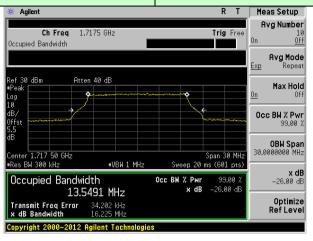


Highest channel

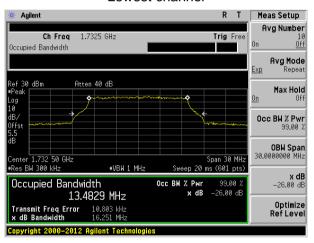


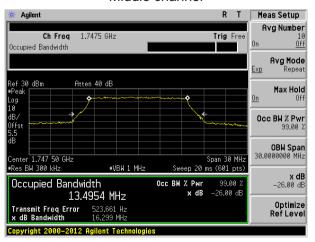
Test band: LTE Band 4

Channel Bandwidth: 15MHz



Lowest channel



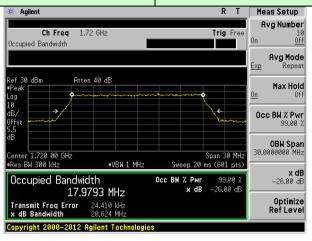


Highest channel

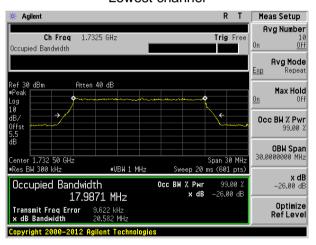


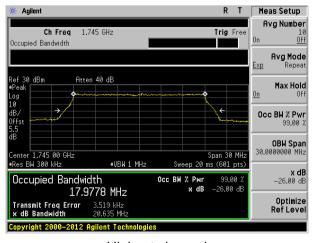
Test band: LTE Band 4

Channel Bandwidth: 20MHz



Lowest channel



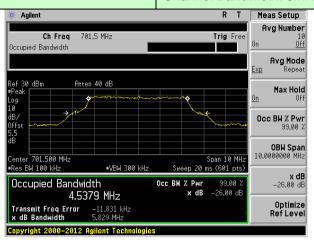


Highest channel

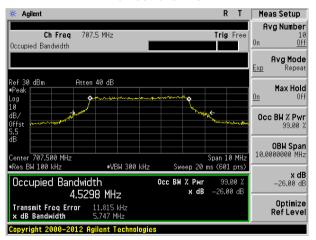


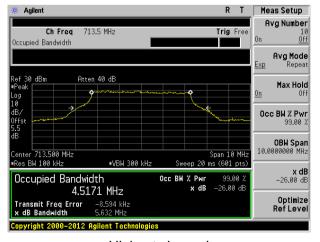
Test band: LTE Band 12

Channel Bandwidth: 5MHz



Lowest channel



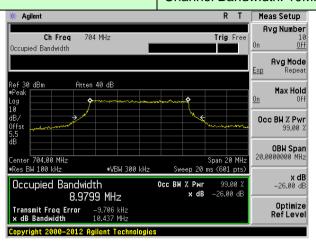


Highest channel

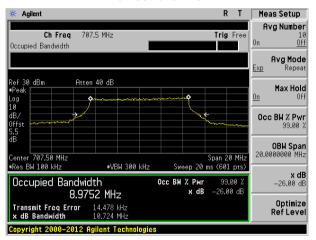


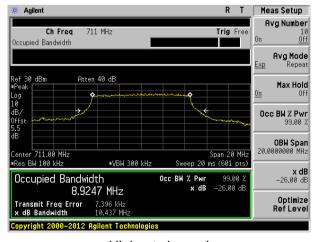
Test band: LTE Band 12

Channel Bandwidth: 10MHz



Lowest channel





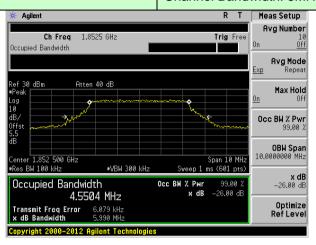
Highest channel



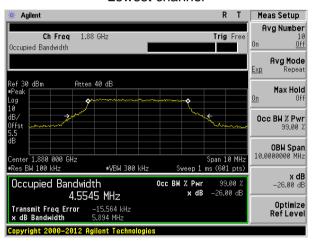
16QAM mode:

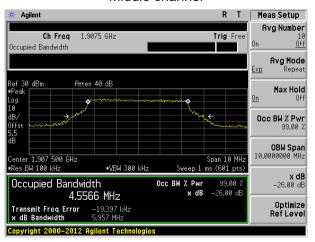
Test band: LTE Band 2

Channel Bandwidth: 5MHz



Lowest channel



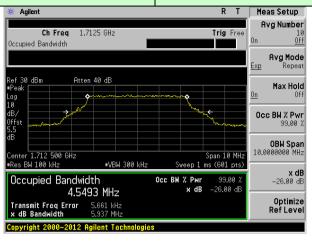


Highest channel

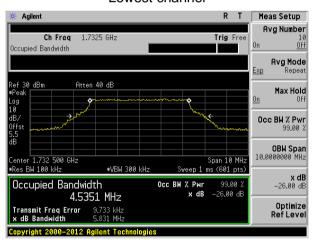


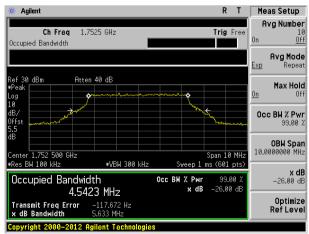
Test band: LTE Band 4

Channel Bandwidth: 5MHz



Lowest channel



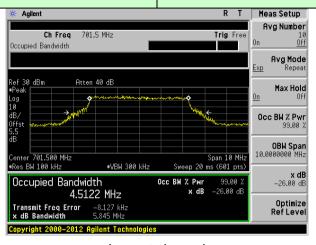


Highest channel

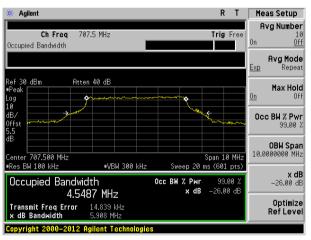


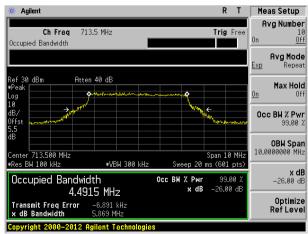
Test band: LTE Band 12

Channel Bandwidth: 5MHz



Lowest channel





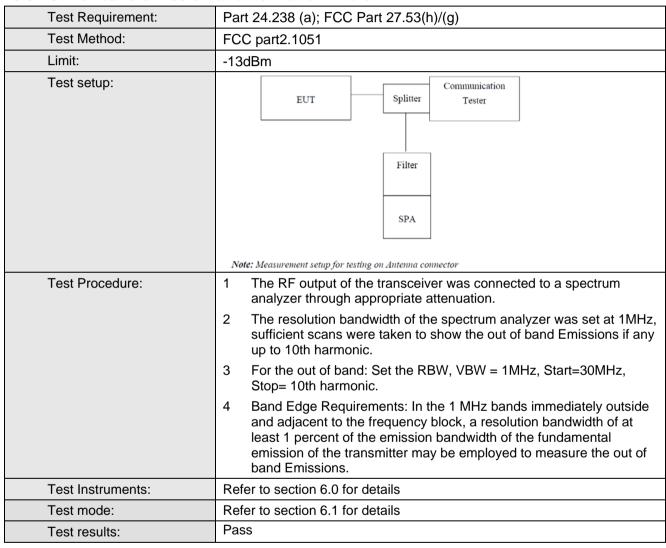
Highest channel



6.5 MODULATION CHARACTERISTIC

According to FCC § 2.1047(d), Part 27 there is no specific requirement for digital modulation, therefore modulation characteristic is not presented.

6.6 Out of band emission at antenna terminals

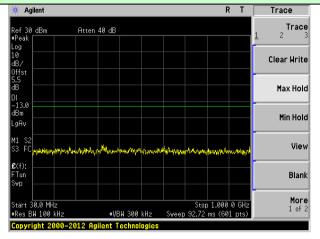


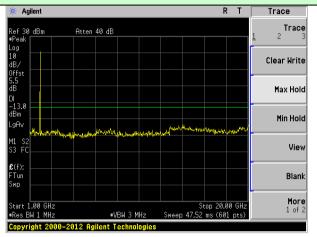
Test plot as follows:



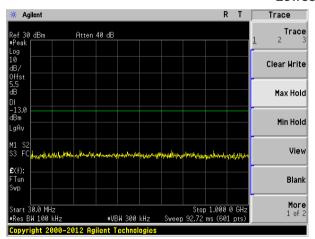
QPSK mode:

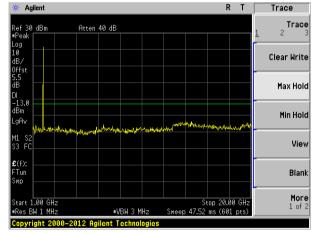
Test Mode: LTE Band 2 Channel Bandwidth: 5MHz



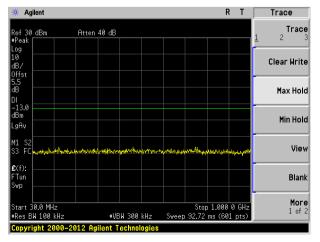


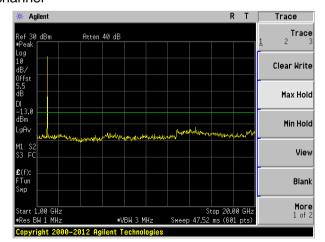
Lowest channel





Middle channel

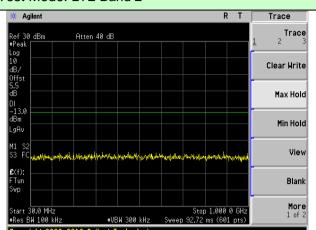




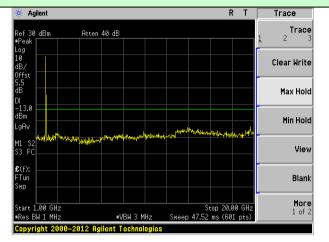
Highest channel



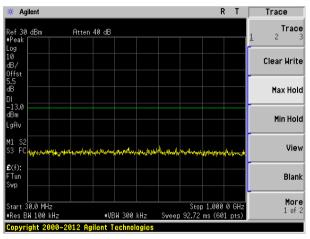
Test Mode: LTE Band 2

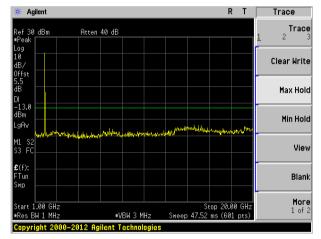


Channel Bandwidth: 10MHz

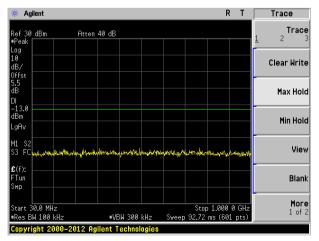


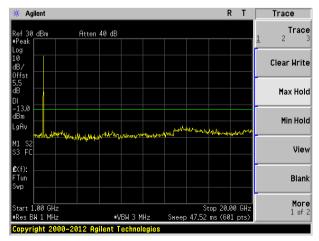
Lowest channel





Middle channel

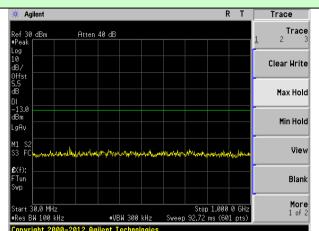




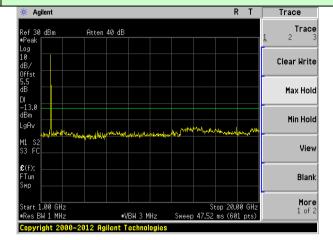
Highest channel



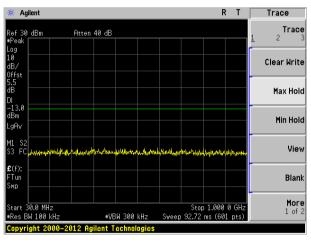
Test Mode: LTE Band 2

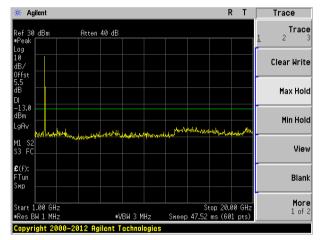


Channel Bandwidth: 15MHz

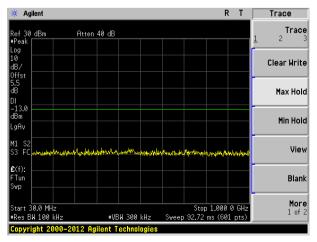


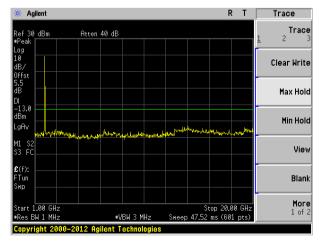
Lowest channel





Middle channel

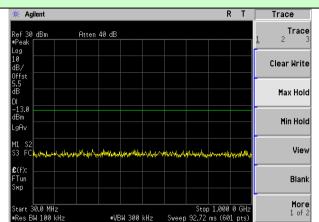




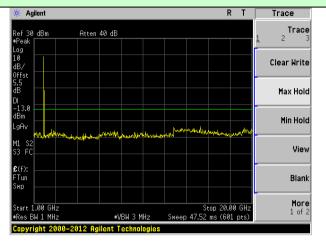
Highest channel



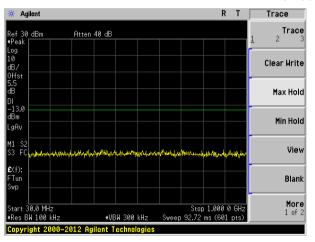
Test Mode: LTE Band 2

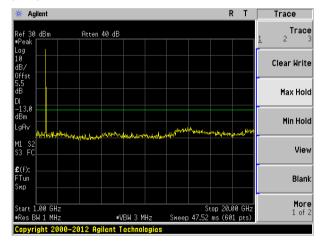


Channel Bandwidth: 20MHz

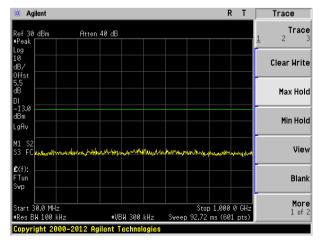


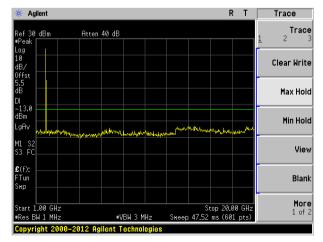
Lowest channel





Middle channel

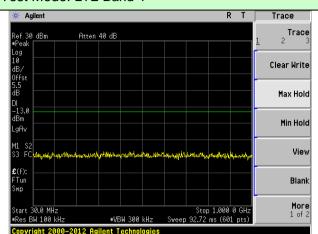




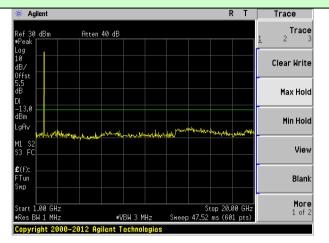
Highest channel



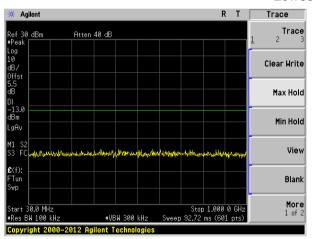
Test Mode: LTE Band 4

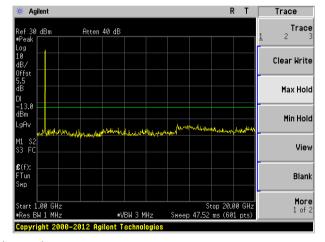


Channel Bandwidth: 5MHz

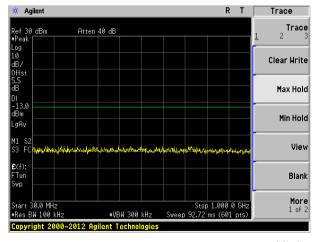


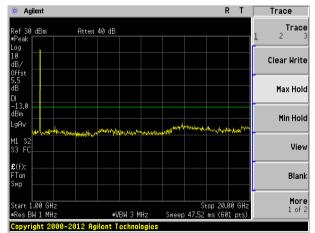
Lowest channel





Middle channel

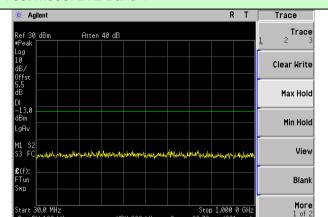




Highest channel

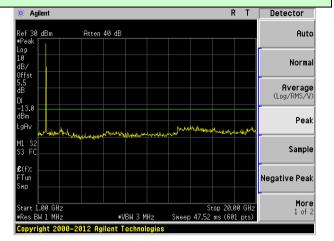


Test Mode: LTE Band 4

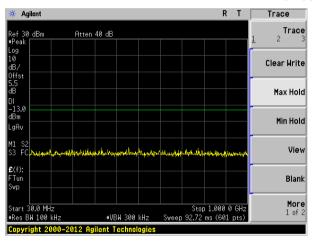


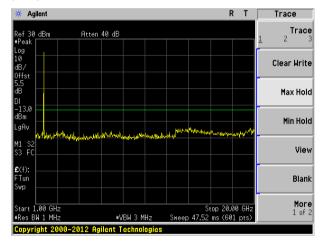
Stop 1.000 0 GH: Sweep 92.72 ms (601 pts)

Channel Bandwidth: 10MHz

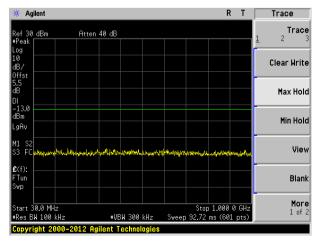


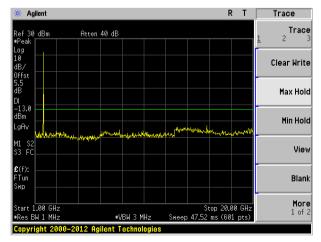
Lowest channel





Middle channel

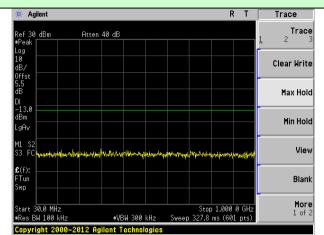




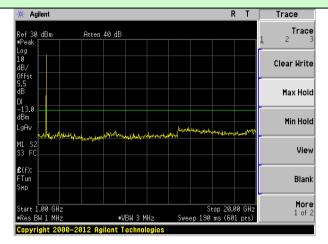
Highest channel



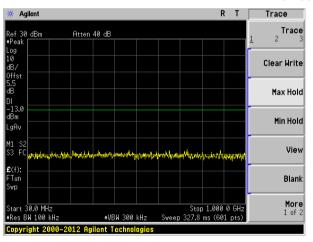
Test Mode: LTE Band 4

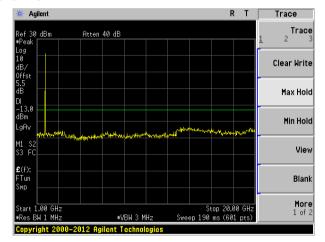


Channel Bandwidth: 15MHz

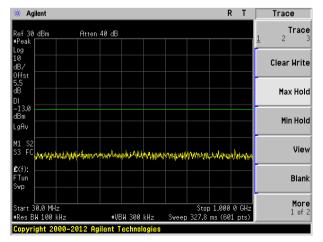


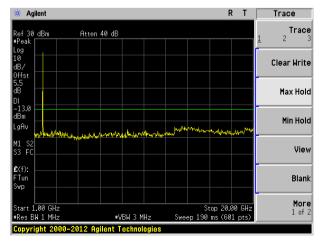
Lowest channel





Middle channel

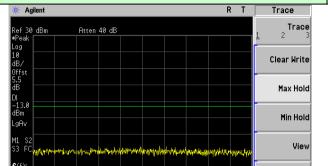




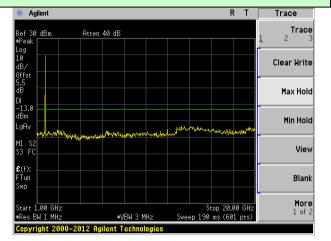
Highest channel



Test Mode: LTE Band 4



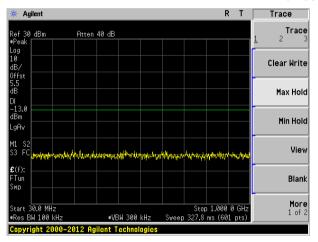
Channel Bandwidth: 20MHz

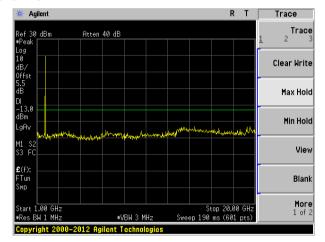


Lowest channel

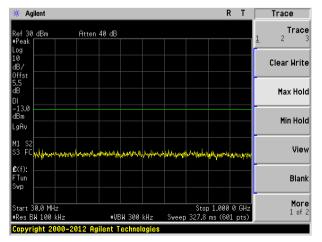
Blank

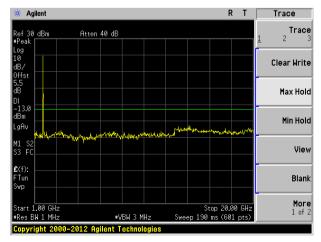
More 1 of 2





Middle channel

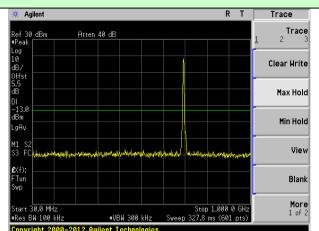




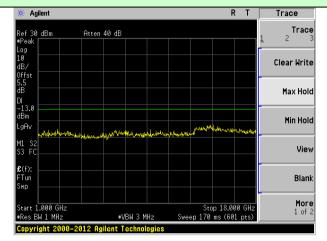
Highest channel



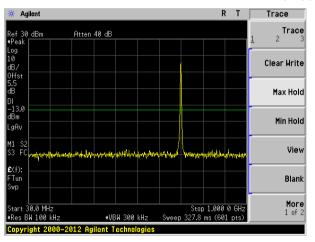
Test Mode: LTE Band 12

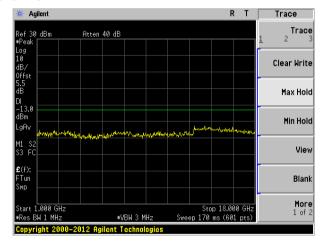


Channel Bandwidth: 5MHz

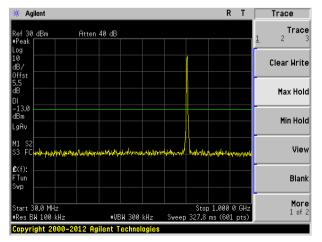


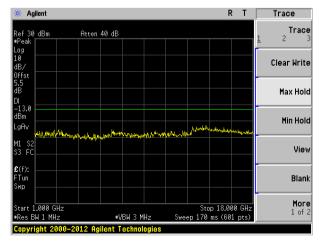
Lowest channel





Middle channel

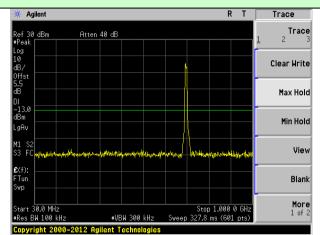




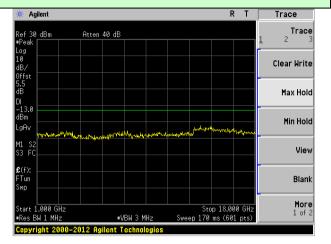
Highest channel



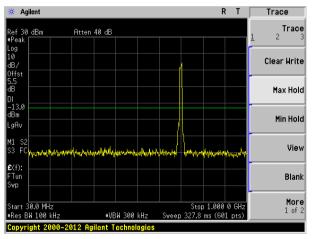
Test Mode: LTE Band 12

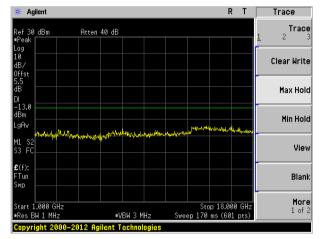


Channel Bandwidth: 10MHz

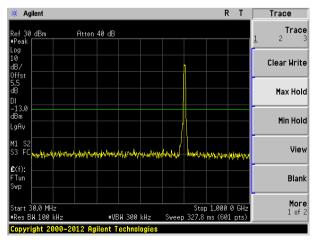


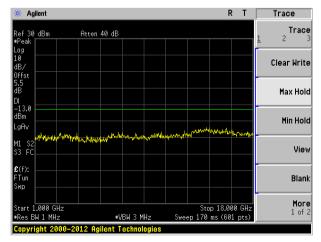
Lowest channel





Middle channel



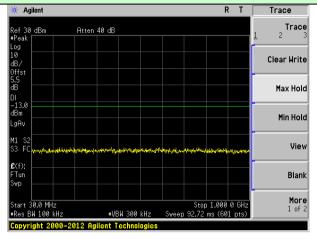


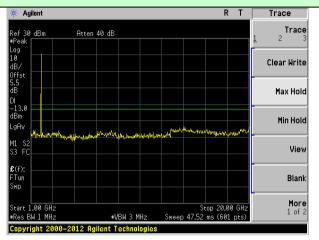
Highest channel



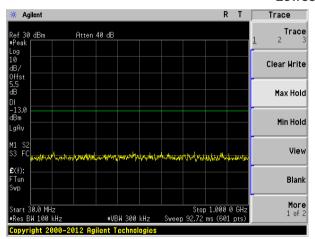
16QAM mode:

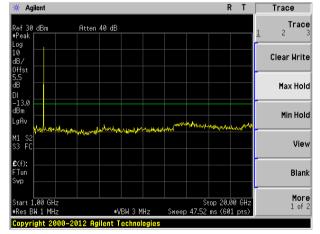
Test Mode: LTE Band 2 Channel Bandwidth: 5MHz



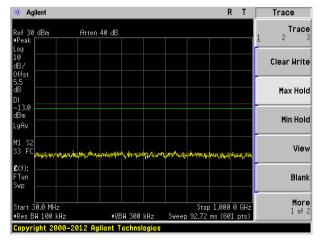


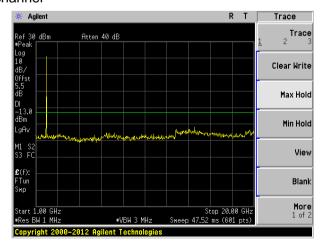
Lowest channel





Middle channel

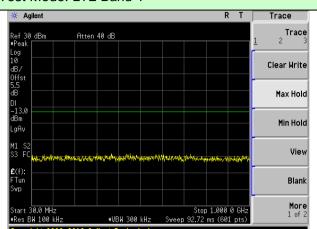




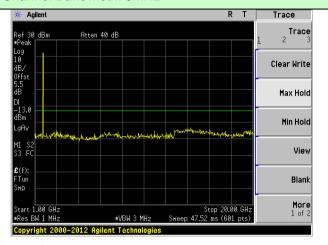
Highest channel



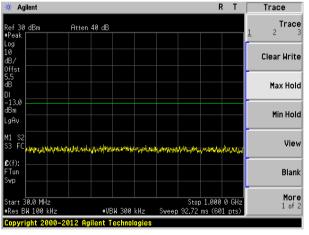
Test Mode: LTE Band 4

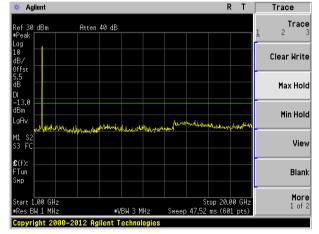


Channel Bandwidth: 5MHz

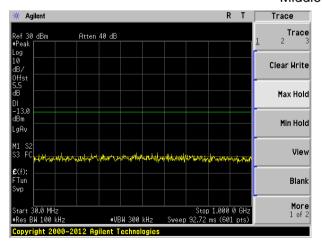


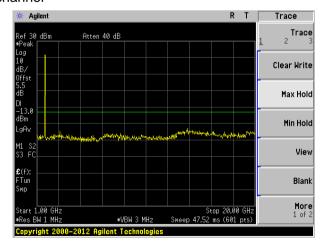
Lowest channel





Middle channel

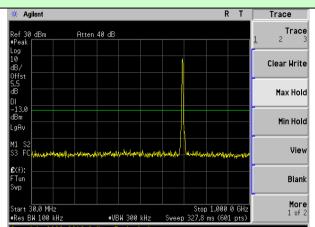




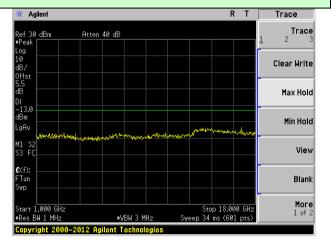
Highest channel



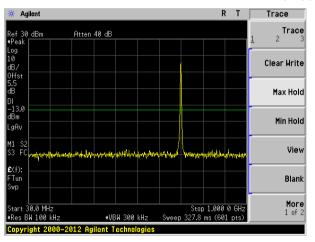
Test Mode: LTE Band 12

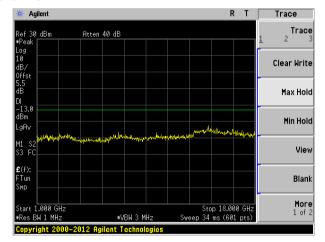


Channel Bandwidth: 5MHz

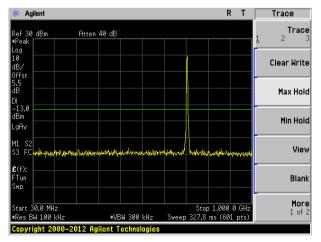


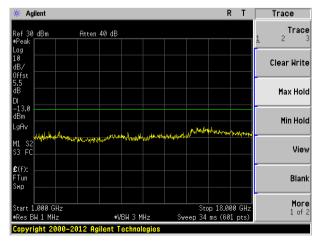
Lowest channel





Middle channel





Highest channel



Trace

Clear Write

Max Hold

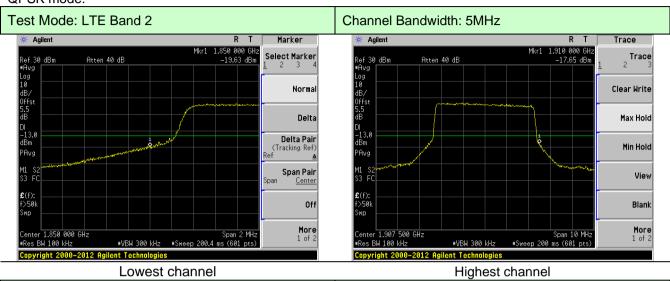
Min Hold

View

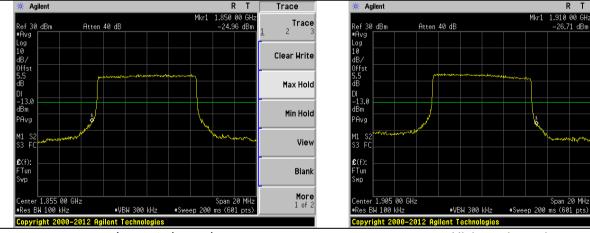
Blank

More 1 of 2

Band Edge: QPSK mode:

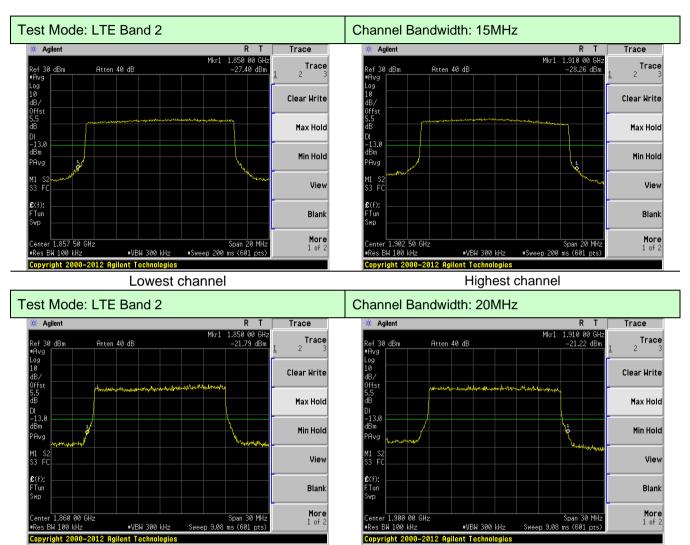


Test Mode: LTE Band 2 Channel Bandwidth: 10MHz Agilent Agilent R T Trace Trace



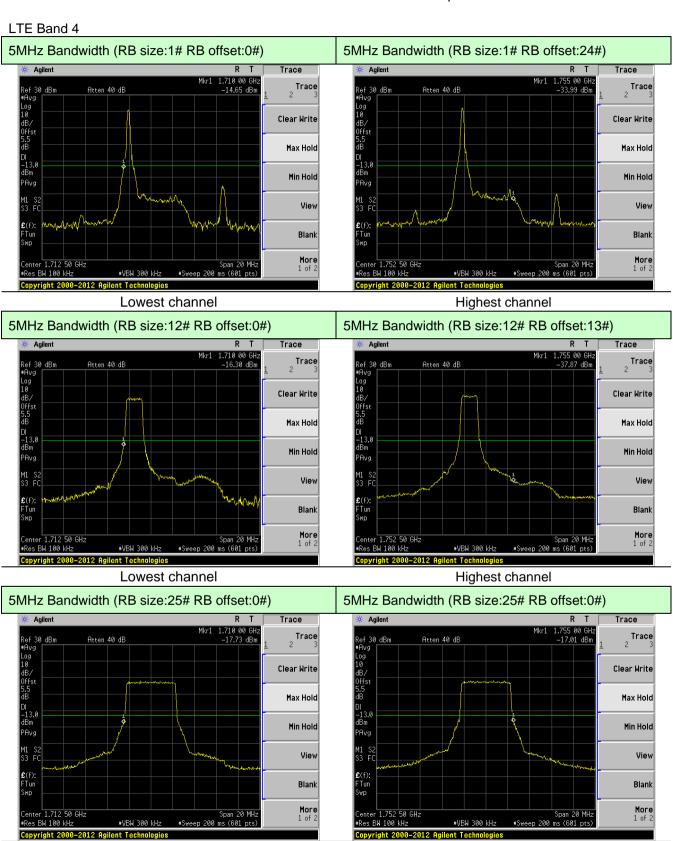
Lowest channel Highest channel





Lowest channel Highest channel





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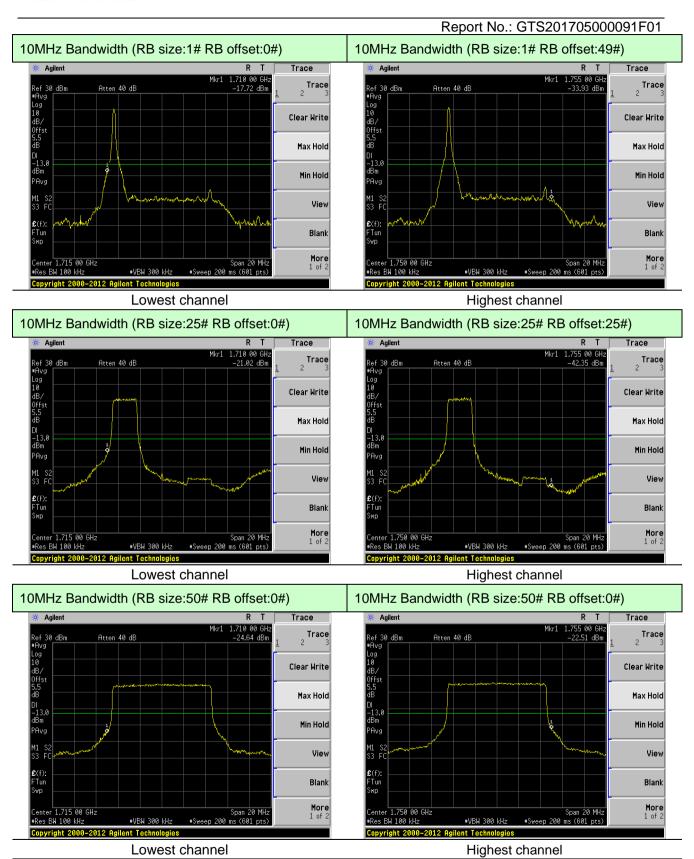
No. 301-309, 3/F., Jinyuan Business Building, No.2, Laodong Industrial Zone, Xixiang Road, Baoan District, Shenzhen, Guangdong, China 518102

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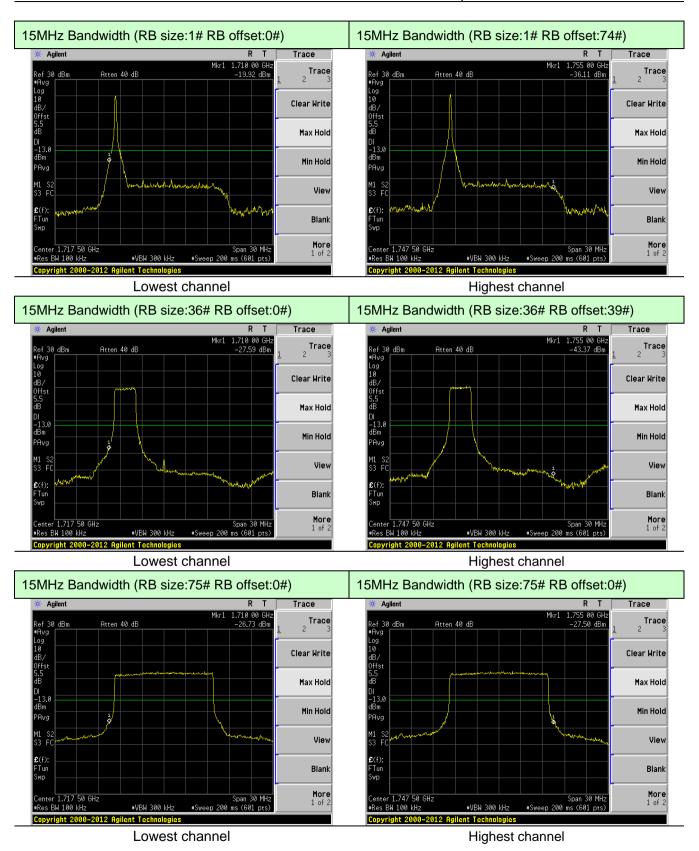
Lowest channel

Highest channel







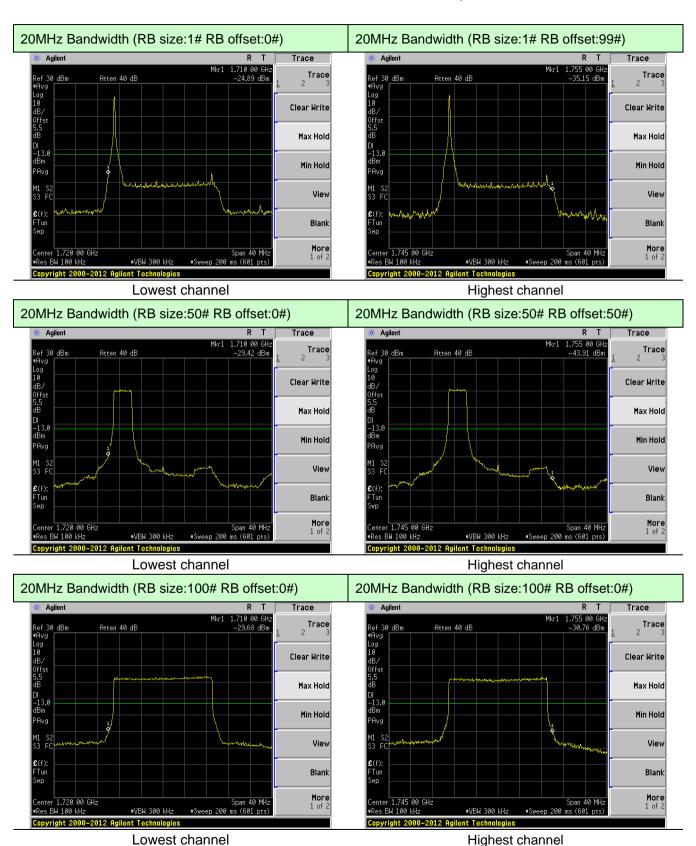


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Page 49 of 96





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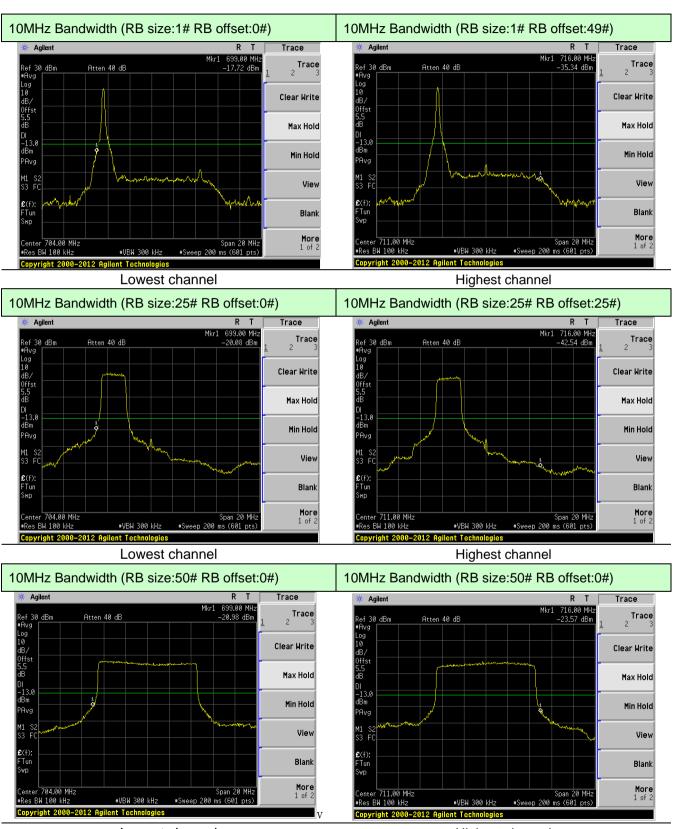


LTE Band 12(QPSK mode): 5MHz Bandwidth (RB size:1# RB offset:0#) 5MHz Bandwidth (RB size:1# RB offset:24#) R T Agilent 699.000 MH: -15.22 dBm 716.000 MHz –33.35 dBm Trace Trace Atten 40 dB Atten 40 dB Ref 30 dBm Clear Write Clear Write Max Hold Max Hold Min Hold Min Hold View View Blank Blank More More 1 of 2 #VBW 300 kHz #VBW 300 kHz Copyright 2000-2012 Agilent Technologies Copyright 2000-2012 Agilent Technologies Lowest channel Highest channel 5MHz Bandwidth (RB size:12# RB offset:0#) 5MHz Bandwidth (RB size:12# RB offset:13#) * Agilent Trace Trace 716.000 MH -37.00 dBm Atten 40 dB Atten 40 dB Clear Write Clear Write Max Hold Max Hold Min Hold Min Hold View View Blank Blank Span 10 MHz #Sweep 200 ms (601 pts) More 1 of 2 More 1 of 2 Span 10 MH: #Sweep 200 ms (601 pts 701.500 MHz #VBW 300 kHz #VBW 300 kHz Lowest channel Highest channel 5MHz Bandwidth (RB size:25# RB offset:0#) 5MHz Bandwidth (RB size:25# RB offset:0#) Trace Atten 40 dB Trace Atten 40 dB Clear Write Clear Write Max Hold Max Hold Min Hold Min Hold View View Blank Blank More 1 of 2 More 1 of 2

Lowest channel Highest channel

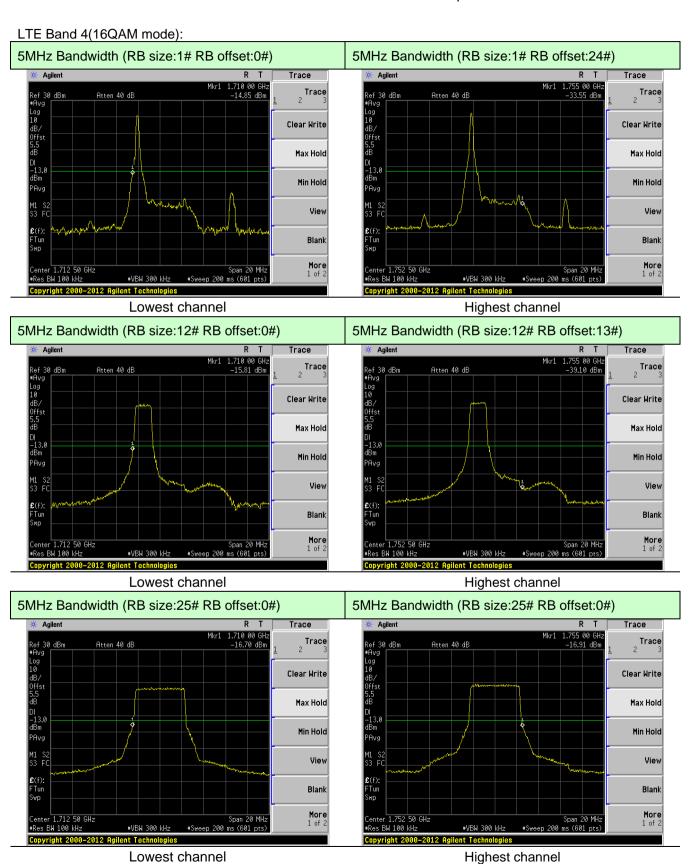
#VBW 300 kHz





Lowest channel Highest channel



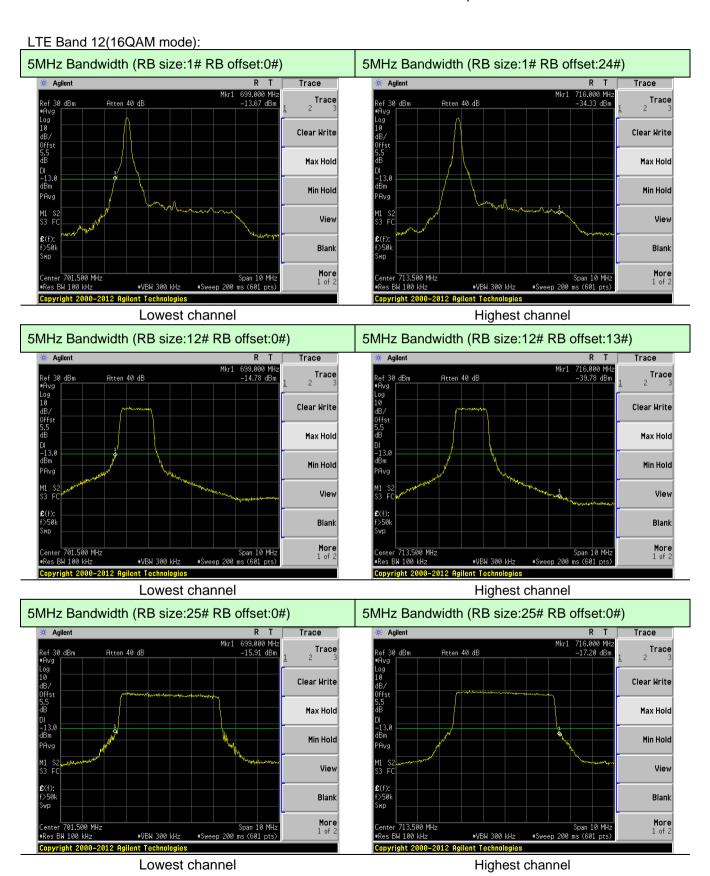


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Page 53 of 96



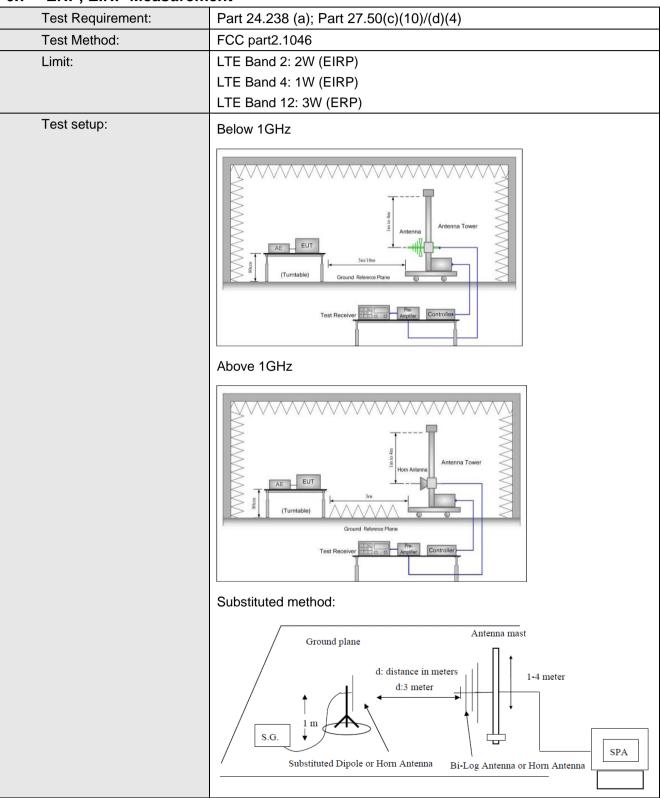


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6.7 ERP, EIRP Measurement





Test Procedure:	The EUT was placed on an non-conductive turntable using a non-conductive support. The radiated emission at the fundamental frequency was measured at 3 m with a test antenna and EMI spectrum analyzer.
	 During the measurement, the EUT was communication with the station. The highest emission was recorded with the rotation of the turntable and the lowering of the test antenna from 4m to 1m. The reading was recorded and the field strength (E in dBuV/m) was calculated.
	3. ERP in frequency band 777–787MHz were measured using a substitution method. The EUT was replaced by dipole antenna connected, the S.G. output was recorded and ERP was calculated asfollows:
	ERP = S.G. output (dBm) + Antenna Gain (dBd) - Cable Loss (dB)
	4. EIRP in frequency band 1710–1755MHz were measured using a substitution method. The EUT was replaced by or horn antenna connected, the S.G. output was recorded and EIRP was calculated as follows:
	EIRP = S.G. output (dBm) + Antenna Gain (dBi) - Cable Loss (dB)
Test Instruments:	Refer to section 6.0 for details
Test mode:	Refer to section 6.1 for details
Test results:	Pass

Measurement Data



QPSK mode:

EUT mode	Channel	EUT Pol.	Antenna Pol.	EIRP(dBm)	Limit (dBm)	Result
		Н	V	22.52		
		П	Н	20.47		
	Lawaat	E1	V	22.18	22.00	Door
	Lowest		Н	19.79	33.00	Pass
		E2	V	21.39		
		E2	Н	18.55		
		Н	V	22.50		Pass
	Middle		Н	19.80	33.00	
LTE Band 2		E1	V	22.04		
(5MHz)	ivildale		Н	19.57		
		F0	V	21.89		
		E2	Н	18.77		
		Н	V	22.24		
		11	Н	19.95		
	Highoot	E1	V	22.01	33.00	Door
Highest	підпезі		Н	19.68		Pass
		F0	V	21.75		
		E2	Н	19.16		



EUT mode	Channel	EUT Pol.	Antenna Pol.	EIRP (dBm)	Limit (dBm)	Result
		Н	V	22.62		
		П	Н	20.59		
	Laurant	E1	V	22.32	22.00	Dave
	Lowest		Н	19.93	33.00	Pass
		E2	V	21.55		
		E2	Н	18.73		
		Н	V	22.65		Pass
	Middle		Н	19.98	33.00	
LTE Band 2		E1	V	22.24		
(10MHz)	Middle		Н	19.79		
		E2	V	22.08		
		E2	Н	18.96		
		Н	V	22.39		
		П	Н	20.11		
	Lighoot	E1	V	22.19	22.00	Door
"	Highest	ΕΊ	Н	19.87	33.00	Pass
		E2	V	21.88		
			Н	19.30		



EUT mode	Channel	EUT Pol.	Antenna Pol.	EIRP (dBm)	Limit (dBm)	Result
		Н	V	22.70		
		П	Н	20.68		
	Laurant	E1	V	22.42	22.00	Dave
	Lowest		Н	20.05	33.00	Pass
		E2	V	21.67		
		E2	Н	18.86		
		Н	V	22.77		Pass
	Middle	11	Н	20.13	33.00	
LTE Band 2		E1	V	22.39		
(15MHz)			Н	19.95		
		Ε0	V	22.21		
		E2	Н	19.11		
		Н	V	22.51		
		П	Н	20.23		
	Highoot	E1	V	22.32	33.00	Door
'	Highest	Eï	Н	20.02		Pass
		F0	V	21.98		
		E2	Н	19.41		



EUT mode	Channel	EUT Pol.	Antenna Pol.	EIRP (dBm)	Limit (dBm)	Result
		Н	V	22.77		
		П	Н	20.75		
	Laurant	E1	V	22.50	22.00	Dave
	Lowest		Н	20.13	33.00	Pass
		E2	V	21.77		
		E2	Н	18.96		
		Н	V	22.86		Pass
	Middle		Н	20.23	33.00	
LTE Band 2		E1	V	22.51		
(20MHz)	ivildale		Н	20.08		
		F0	V	22.32		
		E2	Н	19.22		
		Н	V	22.59		
		П	Н	20.33		
	Highoot	E1	V	22.42	22.00	Door
	Highest	Eï	Н	20.13	33.00	Pass
		F0	V	22.05		
		E2	Н	19.50		



EUT mode	Channel	EUT Pol.	Antenna Pol.	EIRP(dBm)	Limit (dBm)	Result
		1.1	V	22.71		
		Н	Н	20.69		
	1	Ε4	V	22.42	00.00	Davis
	Lowest	E1	Н	20.05	30.00	Pass
		Fo	V	21.68		
		E2	Н	18.87		
		Н	V	22.77		
	Middle	11	Н	20.13	30.00	Pass
LTE Band 4		E1	V	22.40		
(5MHz)	Middle		Н	19.96		
		E2	V	22.22		
		E2	Н	19.12		
		Н	V	22.51		
		11	Н	20.24		
	Lighoot	E1	V	22.33	20.00	Poss
Highest	ET	Н	20.03	30.00	Pass	
		50	V	21.98		
		E2	EZ	Н	19.42	



EUT mode	Channel	EUT Pol.	Antenna Pol.	EIRP(dBm)	Limit (dBm)	Result
		Н	V	22.59		
		П	Н	20.55		
	1	E1	V	22.28	00.00	Davis
	Lowest	E1	Н	19.89	30.00	Pass
		Ε0	V	21.50		
		E2	Н	18.67		
		Н	V	22.61		
	Middle	11	Н	19.93	30.00	Pass
LTE Band 4		E1	V	22.18		
(10MHz)	Middle		Н	19.72		
		E2	V	22.02		
		E2	Н	18.90		
		Н	V	22.35		
		П	Н	20.06		
	Llighoot	⊑ 1	V	22.13	20.00	Door
Highest	nignest	E1	Н	19.82	30.00	Pass
		E2	V	21.84		
			Н	19.26		



EUT mode	Channel	EUT Pol.	Antenna Pol.	EIRP(dBm)	Limit (dBm)	Result
		Н	V	22.55		
		П	Н	20.51		
	Laurant	E1	V	22.23	20.00	Dana
	Lowest		Н	19.84	30.00	Pass
		F2	V	21.44		
		E2	Н	18.61		
		Н	V	22.55		Pass
	Midalo		Н	19.86	30.00	
LTE Band 4		E1	V	22.11		
(15MHz)	Middle		Н	19.64		
		F0	V	21.95		
		E2	Н	18.83		
		Н	V	22.29		
		П	Н	20.00		
	Highoot	E1	V	22.07	20.00	Pass
	Highest		Н	19.75	30.00	
		E2	V	21.79		
			Н	19.21		



EUT mode	Channel	EUT Pol.	Antenna Pol.	EIRP(dBm)	Limit (dBm)	Result
		Н	V	21.17		
		П	Н	18.69		
	1	E1	V	21.52	00.00	Davis
	Lowest	E1	Н	18.44	30.00	Pass
		Ε0	V	20.92		
		E2	Н	17.97		
		н	V	22.08		Pass
	Middle		Н	19.67	30.00 Pa	
LTE Band 4		E1	V	21.90		
(20MHz)	Middle		Н	19.41		
		E2	V	21.43		
			Н	18.19		
		Н	V	21.89		
		П	Н	19.81		
	Llighoot	⊑ 1	V	21.85	20.00	Door
Highest	nignest	E1	Н	19.34	30.00	Pass
		E2	V	21.31		
			Н	18.70		



EUT mode	Channel	EUT Pol.	Antenna Pol.	ERP(dBm)	Limit (dBm)	Result
		Н	V	22.75		
		П	Н	20.73		
		E1	V	22.47	0.4.77	
	Lowest	<u> </u>	Н	20.10	34.77	Pass
		F0	V	21.74		
		E2	Н	18.93		
		Н	V	22.83		Pass
	M de all a	П	Н	20.20	34.77	
LTE Band 12		E1	V	22.47		
(5MHz)	Middle		Н	20.03		
			V	22.28		
		E2	Н	19.19		
		Ш	V	22.57		
		Н	Н	20.30		
	l limboot		V	22.39	24.77	Door
Highest	Hignest	E1	Н	20.09	34.77	Pass
		F.0	V	22.03		
		E2	Н	19.47		



EUT mode	Channel	EUT Pol.	Antenna Pol.	ERP(dBm)	Limit (dBm)	Result
		Н	V	22.69		
		П	Н	20.66		
		Ε4	V	22.40	0.4.77	
	Lowest	E1	Н	20.02	34.77	Pass
		F0	V	21.65		
		E2	Н	18.83		
		н	V	22.75		Pass
	A4: 1 H		Н	20.10	34.77	
LTE Band 12		E1	V	22.36		
(10MHz)	Middle		Н	19.92		
			V	22.18		
		E2	Н	19.08		
		11	V	22.48		
		Н	Н	20.21		
	I Pakaat	Γ4	V	22.29	0.4.77	Davis
	Highest	E1	Н	19.99	34.77	Pass
			V	21.96		
		E2	EZ	Н	19.39	



16QAM mode:

EUT mode	Channel	EUT Pol.	Antenna Pol.	EIRP(dBm)	Limit (dBm)	Result
		Н	V	22.55		
		П	Н	20.51		
	Lawaat	E1	V	22.23	20.00	Daga
	Lowest		Н	19.84	30.00	Pass
		E2	V	21.45		
			Н	18.61		
		Н	V	22.55		
	Middle	11	Н	19.86	30.00	Pass
LTE Band 2		E1	V	22.11		
(5MHz)	Middle		Н	19.65		
		E2	V	21.96		
		LZ	Н	18.83		
		Н	V	22.29		
		11	Н	20.00		
	Highest	E1	V	22.07	30.00	Pass
	i ligilest		Н	19.75		Pass
		E2	V	21.79		
		L2	Н	19.21		



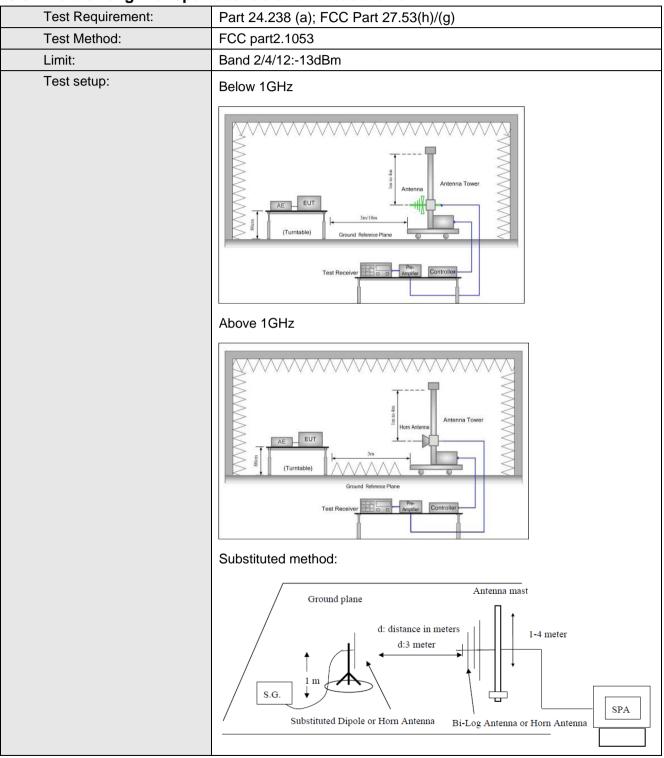
EUT mode	Channel	EUT Pol.	Antenna Pol.	EIRP(dBm)	Limit (dBm)	Result
LTE Band 4 (5MHz)	Lowest	Н	V	22.69		Pass
			Н	20.66	30.00	
		E1	V	22.40		
			Н	20.02		
		E2	V	21.64		
			Н	18.83		
	Middle	Н	V	22.74	30.00	Pass
			Н	20.09		
		E1	V	22.36		
			Н	19.91		
		E2	V	22.18		
			Н	19.08		
	Highest	Н	V	22.48	30.00	Pass
			Н	20.21		
		E1	V	22.29		
			Н	19.98		
		E2	V	21.95		
			Н	19.39		



EUT mode	Channel	EUT Pol.	Antenna Pol.	ERP(dBm)	Limit (dBm)	Result
	Lowest	Н	V	22.73		Pass
			Н	20.71	34.77	
		E1	V	22.45		
			Н	20.08		
		E2	V	21.71		
			Н	18.90		
	Middle	Н	V	22.80	34.77	Pass
LTE Band 12 (5MHz)			Н	20.16		
		E1	V	22.44		
			Н	20.00		
		E2	V	22.25		
			Н	19.15		
	Highest	Н	V	22.54	34.77	Pass
			Н	20.27		
		E1	V	22.36		
			Н	20.06		
		E2	V	22.00		
			Н	19.44		



6.8 Field strength of spurious radiation measurement





Test Procedure:	The EUT was placed on an non-conductive turntable using a non-conductive support. The radiated emission at the fundamental frequency was measured at 3 m with a test antenna and EMI spectrum analyzer.
	2. During the tests, the antenna height and the EUT azimuth were varied in order to identify the maximum level of emissions from the EUT. This maximization process was repeated with the EUT positioned in each of its three orthogonal orientations.
	3. The frequency range up to tenth harmonic was investigated for each of three fundamental frequency (low, middle and high channels). Once spurious emission was identified, the power of the emission was determined using the substitution method.
	4. The spurious emissions attenuation was calculated as the difference between radiated power at the fundamental frequency and the spurious emissions frequency.
	ERP / EIRP = S.G. output (dBm) + Antenna Gain(dB/dBi) -
	Cable Loss (dB)
Test Instruments:	Refer to section 6.0 for details
Test mode:	Refer to section 6.1 for details
Test results:	Pass



Measurement Data

QPSK mode:

Test mode:	LTE Band 2(5MHz)		Test channel:	Lowest	
		Emission			
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result	
3705.00	Vertical	-35.28		Pass	
5557.50	V	-37.83			
7410.00	V	-40.59	-13.00		
9262.50	V	-43.52			
11115.00	V				
3705.00	Horizontal	-38.83		Pass	
5557.50	Н	-41.41			
7410.00	Н	-42.91	-13.00		
9262.50	Н	-49.25			
11115.00	Н				
Test mode:	LTE Band	d 2(5MHz)	Test channel:	Middle	
(NALL_)	Spurious Emission		Limit (dDay)	Decult	
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result	
3760.00	Vertical	-37.16		Pass	
5640.00	V	-38.57			
7520.00	V	-42.30	-13.00		
9400.00	V	-44.80			
11280.00	V				
3760.00	Horizontal	-39.78		Pass	
5640.00	Н	-41.82			
7520.00	Н	-46.62	-13.00		
9400.00	Н	-49.15			
11280.00	Н				
Test mode:	LTE Band	d 2(5MHz)	Test channel:	Highest	
Frequency (MHz)	Spurious Emission		Limit (dBm)	Result	
r requericy (IVITIZ)	Polarization	Level (dBm)	LIIIII (UDIII)	Kesuit	
3815.00	Vertical	-35.08			
5722.50	V	-38.92		Pass	
7630.00	V	-41.77	-13.00		
9537.50	V	-39.33			
11445.00	V				
3815.00	Horizontal	-38.06		Pass	
5722.50	Н	-40.89			
7630.00	Н	-46.41	-13.00		
9537.50	Н	-50.18	<u> </u>		
11445.00	Н				



Test mode:	LTE Band	2(10MHz)	Test channel:	Lowest	
	Spurious	Emission			
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result	
3810.00	Vertical	-37.47			
5715.00	V	-40.26			
7620.00	V	-42.56	-13.00	Pass	
9525.00	V	-44.76			
11430.00	V				
3810.00	Horizontal	-42.80			
5715.00	Н	-46.73			
7620.00	Н	-48.34	-13.00	Pass	
9525.00	Н	-51.14			
11430.00	Н				
Test mode:	LTE Band	2(10MHz)	Test channel:	Middle	
[Spurious	Emission	Limit (dDay)		
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result	
3760.00	Vertical	-37.88			
5640.00	V	-40.88			
7520.00	V	-43.37	-13.00	Pass	
9400.00	V	-45.72			
11280.00	V				
3760.00	Horizontal	-43.62			
5640.00	Н	-47.85			
7520.00	Н	-49.59	-13.00	Pass	
9400.00	Н	-52.61			
11280.00	Н				
Test mode:	LTE Band	2(10MHz)	Test channel:	Highest	
Francisco (MIII-)	Spurious	Emission	Linnit (dDno)	Dagult	
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result	
3710.00	Vertical	-37.74			
5565.00	V	-40.87			
7420.00	V	-43.46	-13.00	Pass	
9275.00	V	-45.93			
11130.00	V				
3710.00	Horizontal	-43.73			
5565.00	Н	-48.15			
7420.00	Н	-49.96	-13.00	Pass	
9275.00	Н	-53.10			
11130.00	Н				



Test mode:	LTE Band	2(15MHz)	Test channel:	Lowest	
		Emission			
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result	
3805.00	Vertical	-34.86			
5707.50	V	-37.29			
7610.00	V	-39.32	-13.00	Pass	
9512.50	V	-41.23			
11415.00	V				
3805.00	Horizontal	-39.52			
5707.50	Н	-42.97			
7610.00	Н	-44.37	-13.00	Pass	
9512.50	Н	-46.82			
11415.00	Н				
Test mode:	LTE Band	2(15MHz)	Test channel:	Middle	
(\A)	Spurious	Emission	Limit (dDay)	D !:	
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result	
3760.00	Vertical	-33.94			
5640.00	V	-36.43			
7520.00	V	-38.51	-13.00	Pass	
9400.00	V	-40.49			
11280.00	V				
3760.00	Horizontal	-38.73			
5640.00	Н	-42.26			
7520.00	Н	-43.71	-13.00	Pass	
9400.00	Н	-46.21			
11280.00	Н				
Test mode:	LTE Band	2(15MHz)	Test channel:	Highest	
(\A)	Spurious	Emission	Limit (dDay)	Danult	
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result	
3715.00	Vertical	-35.48			
5572.50	V	-37.93			
7430.00	V	-39.98	-13.00	Pass	
9287.50	V	-41.90	7		
11145.00	V				
3715.00	Horizontal	-40.18			
5572.50	Н	-43.65			
7430.00	Н	-45.07	-13.00	Pass	
9287.50	Н	-47.53			
11145.00	Н				



Test mode:	I TF Band	2(20MHz)	Test channel:	Lowest
		Emission	Tool Gridinion	2011001
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result
3800.00	Vertical	-35.85		
5700.00	V	-37.96		
7600.00	V	-39.71	-13.00	Pass
9500.00	V	-41.35		
11400.00	V			
3800.00	Horizontal	-39.87		
5700.00	Н	-42.84		
7600.00	Н	-44.08	-13.00	Pass
9500.00	Н	-46.21		
11400.00	Н			
Test mode:	LTE Band	2(20MHz)	Test channel:	Middle
	Spurious	Emission	Lineit (dDas)	Desult
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result
3760.00	Vertical	-37.09		
5640.00	V	-39.37		Pass
7520.00	V	-41.28	-13.00	
9400.00	V	-43.09		
11280.00	V			
3760.00	Horizontal	-41.48		
5640.00	Н	-44.71		
7520.00	Н	-46.03	-13.00	Pass
9400.00	Н	-48.33		
11280.00	Н			
Test mode:	LTE Band	2(20MHz)	Test channel:	Highest
Francisco (MIII-)	Spurious	Emission	Linnit (dDmn)	Decult
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result
3720.00	Vertical	-34.43		
5580.00	V	-37.23		
7440.00	V	-39.57	-13.00	Pass
9300.00	V	-41.75		
11160.00	V			
3720.00	Horizontal	-39.78		
5580.00	Н	-43.74		
7440.00	Н	-45.38	-13.00	Pass
9300.00	Н	-48.21	_	. 4.00
11160.00	Н			



Test mode:	LTE Band	d 4(5MHz)	Test channel:	Lowest
	Spurious	Emission		
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result
3425.00	Vertical	-35.49		
5137.50	V	-38.25		
6850.00	V	-40.54	-13.00	Pass
8562.50	V	-42.70		
10275.00	V			
3425.00	Horizontal	-40.77		
5137.50	Н	-44.66		
6850.00	Н	-46.26	-13.00	Pass
8562.50	Н	-49.02		
10275.00	Н			
Test mode:	LTE Band	d 4(5MHz)	Test channel:	Middle
Figure (NALL)	Spurious	Emission	L''(/ ID)	D 11
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result
3465.00	Vertical	-37.58		
5197.50	V	-39.84		Pass
6930.00	V	-41.72	-13.00	
8662.50	V	-43.52		
10395.00	V			
3465.00	Horizontal	-41.93		
5197.50	Н	-45.14		
6930.00	Н	-46.43	-13.00	Pass
8662.50	Н	-48.69		
10395.00	Н			
Test mode:	LTE Band	d 4(5MHz)	Test channel:	Highest
(NALL=)	Spurious	Emission	Lineit (dDne)	Danult
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result
3505.00	Vertical	-36.82		
5257.50	V	-38.88		
7010.00	V	-40.59	-13.00	Pass
8762.50	V	-42.21		
10515.00	V			
3505.00	Horizontal	-40.76		
5257.50	Н	-43.68		
7010.00	Н	-44.87	-13.00	Pass
8762.50	Н	-46.94		
10515.00	Н			



Test mode:	LTE Band	d 4(10MHz)	Test channel:	Lowest	
- (A411)	Spurious	Emission	l: :(/ID)	5	
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result	
3430.00	Vertical	-35.34			
5145.00	V	-37.80	-13.00		
6860.00	V	-39.85		Pass	
8575.00	V	-41.77			
10290.00	V				
3430.00	Horizontal	-40.05			
5145.00	Η	-43.52			
6860.00	Н	-44.95	-13.00	Pass	
8575.00	Н	-47.42			
10290.00	Η				
Test mode:	LTE Band	d 4(10MHz)	Test channel:	Middle	
Fragues as (MIII-)	Spurious	Emission	Lineit (dDne)		
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result	
3465.00	Vertical	-33.83			
5197.50	V	-36.33			
6930.00	V	-38.41	-13.00	Pass	
8662.50	V	-40.39			
10395.00	V				
3465.00	Horizontal	-38.63			
5197.50	Н	-42.17			
6930.00	Η	-43.62	-13.00	Pass	
8662.50	Н	-46.13			
10395.00	Н				
Test mode:	LTE Band	d 4(10MHz)	Test channel:	Highest	
Frequency (MHz)	Spurious	Emission	Limit (dBm)	Result	
Frequency (MHZ)	Polarization	Level (dBm)	LIIIII (UDIII)	Result	
3500.00	Vertical	-34.74			
5250.00	V	-37.18			
7000.00	V	-39.21	-13.00	Pass	
8750.00	V	-41.13			
10500.00	V				
3500.00	Horizontal	-39.41			
5250.00	Н	-42.87			
7000.00	Н	-44.28	-13.00	Pass	
8750.00	Н	-46.73			
10500.00	Η				



Test mode:	LTE Band	4(15MHz)	Test channel:	Lowest
	Spurious	Emission		
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result
3435.00	Vertical	-38.43		
5152.50	V	-41.53		
6870.00	V	-44.09	-13.00	Pass
8587.50	V	-46.55		
10305.00	V			
3435.00	Horizontal	-44.37		
5152.50	Н	-48.75		
6870.00	Н	-50.53	-13.00	Pass
8587.50	Н	-53.62		
10305.00	Н			
Test mode:	LTE Band	4(15MHz)	Test channel:	Middle
- (1411)	Spurious	Emission		5 "
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result
3465.00	Vertical	-38.73		
5197.50	V	-41.69		
6930.00	V	-44.13	-13.00	Pass
8662.50	V	-46.48		
10395.00	V			
3465.00	Horizontal	-44.40		
5197.50	Н	-48.58		
6930.00	Н	-50.29	-13.00	Pass
8662.50	Н	-53.25		
10395.00	Н			
Test mode:	LTE Band	4(15MHz)	Test channel:	Highest
Face (MILL)	Spurious	Emission	L''(/ ID)	D 11
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result
3495.00	Vertical	-38.15		
5242.50	V	-40.91		
6990.00	V	-43.18	-13.00	Pass
8737.50	V	-45.37		
10485.00	V			
3495.00	Horizontal	-43.43		
5242.50	Н	-47.32		
6990.00	Н	-48.90	-13.00	Pass
8737.50	Н	-51.65		
10485.00	Н			



Test mode:	LTE Band	d 4(20MHz)	Test channel:	Lowest	
- (A411.)	Spurious	Emission	(15)	D 1	
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result	
3440.00	Vertical	-34.72			
5160.00	V	-38.58	-13.00		
6880.00	V	-41.45		Pass	
8600.00	V	-39.02			
10320.00	V				
3440.00	Horizontal	-37.73			
5160.00	Н	-40.58			
6880.00	Н	-46.12	-13.00	Pass	
8600.00	Н	-49.91			
10320.00	Н				
Test mode:	LTE Band	4(20MHz)	Test channel:	Middle	
[Spurious	Emission	Lineit (dDas)	D !:	
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result	
3465.00	Vertical	-36.82			
5197.50	V	-38.24			
6930.00	V	-41.99	-13.00	Pass	
8662.50	V	-44.50			
10395.00	V				
3465.00	Horizontal	-39.47			
5197.50	Н	-41.53			
6930.00	Н	-46.34	-13.00	Pass	
8662.50	Н	-48.89			
10395.00	Н				
Test mode:	LTE Band	4(20MHz)	Test channel:	Highest	
Frequency (MHz)	Spurious	Emission	Limit (dBm)	Result	
Frequency (IVII IZ)	Polarization	Level (dBm)	Limit (dbin)	Kesuit	
3490.00	Vertical	-34.91			
5235.00	V	-37.47			
6980.00	V	-40.25	-13.00	Pass	
8725.00	V	-43.19			
10470.00	V				
3490.00	Horizontal	-38.48			
5235.00	Н	-41.08			
6980.00	Н	-42.60	-13.00	Pass	
8725.00	Н	-48.97			
10470.00	Н				

Remark:

- 1. The emission behaviour belongs to narrowband spurious emission.
- 2. Remark"---" means that the emission level is too low to be measured
- 3. The emission levels of below 1 GHz are very lower than the limit and not show in test report.



Test mode:	LTE Band	12(5MHz)	Test channel:	Lowest
	Spurious	Emission		
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result
1559.00	Vertical	-38.17		
2338.50	V	-38.95	-13.00	
3118.00	V	-40.46		Pass
3897.50	V	-42.73		
4677.00	V			
1559.00	Horizontal	-41.51		
2338.50	Н	-43.27		
3118.00	Н	-44.29	-13.00	Pass
3897.50	Н	-47.32		
4677.00	Н			
Test mode:	LTE Band	l 12(5MHz)	Test channel:	Middle
Fragues as (MIII-)	Spurious	Emission	Limsit (alDura)	Daguit
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result
1764.00	Vertical	-38.73		
2646.00	V	-40.94		
3528.00	V	-42.61	-13.00	Pass
4410.00	V	-46.74		
5292.00	V			
1764.00	Horizontal	-42.08		
2646.00	Н	-43.06		Pass
3528.00	Н	-45.38	-13.00	
4410.00	H	-48.57		
5292.00	Н			
Test mode:	LTE Band	12(5MHz)	Test channel:	Highest
Fraguesia (MIII-)	Spurious	Emission	Lineit (dDne)	Result
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result
1569.00	Vertical	-36.05		
2353.50	V	-37.59		
3138.00	V	-39.77	-13.00	Pass
3922.50	V	-40.88		
4707.00	V			
1569.00	Horizontal	-42.05		
2353.50	Н	-46.03		
3138.00	Н	-48.24	-13.00	Pass
3922.50	Н	-51.38		1 400
4707.00	Н			

Remark:

- 1. The emission behaviour belongs to narrowband spurious emission.
- 2. Remark"---" means that the emission level is too low to be measured
- 3. The emission levels of below 1 GHz are very lower than the limit and not show in test report.



Test mode:	LTE Band	12(10MHz)	Test channel:	Lowest	
- (1411)	Spurious	Spurious Emission		5 "	
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result	
1408.00	Vertical	-35.05			
2112.00	V	-37.52	-13.00		
2816.00	V	-39.58		Pass	
3520.00	V	-41.51			
4224.00	V				
1408.00	Horizontal	-39.78			
2112.00	Н	-43.27			
2816.00	Н	-44.71	-13.00	Pass	
3520.00	Н	-47.20			
4224.00	Н				
Test mode:	LTE Band	12(10MHz)	Test channel:	Middle	
[/N] -\	Spurious	Emission	Limit (dDay)		
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result	
1415.00	Vertical	-33.61			
2122.50	V	-36.12			
2830.00	V	-38.21	-13.00	Pass	
3537.50	V	-40.20			
4245.00	V				
1415.00	Horizontal	-38.43			
2122.50	Н	-41.98		Pass	
2830.00	Н	-43.44	-13.00		
3537.50	Н	-45.97			
4245.00	Н				
Test mode:	LTE Band	12(10MHz)	Test channel:	Highest	
Fragues and (MILL)	Spurious	Emission	Line it (dD as)	Decult	
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result	
1422.00	Vertical	-34.50			
2133.00	V	-36.95			
2844.00	V	-38.99	-13.00	Pass	
3555.00	V	-40.91			
4266.00	V		7		
1422.00	Horizontal	-39.19			
2133.00	Н	-42.66	7		
2844.00	Н	-44.08	-13.00	Pass	
3555.00	Н	-46.55			
4266.00	Н				

Remark:

- 1. The emission behaviour belongs to narrowband spurious emission.
- 2. Remark"---" means that the emission level is too low to be measured
- 3. The emission levels of below 1 GHz are very lower than the limit and not show in test report.



16QAM mode:

Test mode:	LTE Band	d 2(5MHz)	Test channel:	Lowest	
_	Spurious	Emission			
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result	
3705.00	Vertical	-33.27			
5557.50	V	-36.13	-13.00		
7410.00	V	-38.52		Pass	
9262.50	V	-40.72			
11115.00	V				
3705.00	Horizontal	-38.72			
5557.50	Н	-42.74			
7410.00	Н	-44.44	-13.00	Pass	
9262.50	Н	-47.34			
11115.00	Н				
Test mode:	LTE Band	d 2(5MHz)	Test channel:	Middle	
(NALL=)	Spurious	Emission	Lineit (dDne)	- I	
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result	
3760.00	Vertical	-36.56			
5640.00	V	-38.87			
7520.00	V	-40.80	-13.00	Pass	
9400.00	V	-42.61			
11280.00	V				
3760.00	Horizontal	-40.99			
5640.00	Н	-44.26		Pass	
7520.00	Н	-45.60	-13.00		
9400.00	Н	-47.93			
11280.00	Н				
Test mode:	LTE Band	d 2(5MHz)	Test channel:	Highest	
Frequency (MHz)		Emission	Limit (dBm)	Result	
	Polarization	Level (dBm)	Littie (dDitt)	rtoouit	
3815.00	Vertical	-34.81			
5722.50	V	-36.96			
7630.00	V	-38.76	-13.00	Pass	
9537.50	V	-40.41			
11445.00	V				
3815.00	Horizontal	-38.90			
5722.50	H	-41.94			
7630.00	Н	-43.22	-13.00	Pass	
9537.50	Н	-45.42			
11445.00	Н				

Remark:

- 4. The emission behaviour belongs to narrowband spurious emission.
- 5. Remark"---" means that the emission level is too low to be measured
- 6. The emission levels of below 1 GHz are very lower than the limit and not show in test report.



Test mode:	LTE Band	d 4(5MHz)	Test channel:	Lowest	
_	Spurious	Emission			
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result	
3425.00	Vertical	-34.60			
5137.50	V	-37.40	-13.00		
6850.00	V	-39.73		Pass	
8562.50	V	-41.91			
10275.00	V				
3425.00	Horizontal	-39.95			
5137.50	Н	-43.90			
6850.00	Н	-45.53	-13.00	Pass	
8562.50	Н	-48.35			
10275.00	Н				
Test mode:	LTE Band	d 4(5MHz)	Test channel:	Middle	
	Spurious	Emission	Lineit (dDae)		
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result	
3465.00	Vertical	-37.17			
5197.50	V	-39.45			
6930.00	V	-41.35	-13.00	Pass	
8662.50	V	-43.16			
10395.00	V				
3465.00	Horizontal	-41.55			
5197.50	Н	-44.78		Pass	
6930.00	Н	-46.10	-13.00		
8662.50	Н	-48.39			
10395.00	Н				
Test mode:	LTE Band	d 4(5MHz)	Test channel:	Highest	
Fraguera, (MIII-)	Spurious	Emission	Linnit (dDno)	Result	
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result	
3505.00	Vertical	-36.01			
5257.50	V	-38.11			
7010.00	V	-39.86	-13.00	Pass	
8762.50	V	-41.49			
10515.00	V				
3505.00	Horizontal	-40.02			
5257.50	Н	-42.98	-13.00		
7010.00	Н	-44.21		Pass	
8762.50	Н	-46.33			
10515.00	Н				

Remark:

- 7. The emission behaviour belongs to narrowband spurious emission.
- 8. Remark"---" means that the emission level is too low to be measured
- 9. The emission levels of below 1 GHz are very lower than the limit and not show in test report.



Test mode:	LTE Band	l 12(5MHz)	Test channel:	Lowest
	Spurious	Emission		
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result
1559.00	Vertical	-36.00		
2338.50	V	-36.88	-13.00	
3118.00	V	-38.49		Pass
3897.50	V	-40.79		
4677.00	V			
1559.00	Horizontal	-39.50		
2338.50	Н	-41.40		
3118.00	Н	-42.51	-13.00	Pass
3897.50	Н	-45.68		
4677.00	Н			
Test mode:	LTE Band	l 12(5MHz)	Test channel:	Middle
Fragues as (MIII-)	Spurious	Emission	Linnit (dDno)	Daguilt
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result
1764.00	Vertical	-36.50		
2646.00	V	-38.80		
3528.00	V	-40.58	-13.00	Pass
4410.00	V	-44.74		
5292.00	V			
1764.00	Horizontal	-40.01		
2646.00	Н	-41.12		Pass
3528.00	Н	-43.55	-13.00	
4410.00	Н	-46.88		
5292.00	Н			
Test mode:	LTE Band	l 12(5MHz)	Test channel:	Highest
Fraguency (MH=)	Spurious	Emission	Limit (dPm)	Result
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Kesuit
1569.00	Vertical	-33.44		
2353.50	V	-35.09		
3138.00	V	-37.40	-13.00	Pass
3922.50	V	-38.55		
4707.00	V			
1569.00	Horizontal	-39.63		
2353.50	Н	-43.77		
3138.00	Н	-46.10	-13.00	Pass
3922.50	Н	-49.41		
4707.00	Н			

Remark:

- 1. The emission behaviour belongs to narrowband spurious emission.
- 2. Remark"---" means that the emission level is too low to be measured
- 3. The emission levels of below 1 GHz are very lower than the limit and not show in test report.



6.9 Frequency stability V.S. Temperature measurement

Test Requirement:	FCC Part2.1055(a)(1)(b)			
Test Method:	FCC Part2.1055(a)(1)(b)			
Limit:	2.5ppm			
Test setup:	Spectrum analyzer Spectrum analyzer Att. Variable Power Supply Note: Measurement setup for testing on Antenna connector			
Test procedure:	 The equipment under test was connected to an external DC power supply and input rated voltage. RF output was connected to a frequency counter or spectrum analyzer via feed through attenuators. The EUT was placed inside the temperature chamber. Set the spectrum analyzer RBW low enough to obtain the desired frequency resolution and measure EUT 25°C operating frequency as reference frequency. Turn EUT off and set the chamber temperature to -20°C. After the temperature stabilized for approximately 30 minutes recorded the frequency. Repeat step measure with 10°C increased per stage until the highest temperature of +50°C reached. 			
Test Instruments:	Refer to section 6.0 for details			
Test mode:	Refer to section 6.1 for details			
Test results:	Pass			



Measurement Data

QPSK mode:

QPSK mode:	ce Frequency: LTE	Band 2 Middle cl	hannel=18900 cl	nannel=1880MH	z
Power supplied		Frequency error			
(Vdc)	Temperature (°C)	Hz	ppm	Limit (ppm)	Result
	-30	33	0.0178		
	-20	37	0.0197		
	-10	32	0.0172		
	0	28	0.0146		
12.0	10	31	0.0165	2.5	Pass
	20	28	0.0146		
	30	42	0.0222		
	40	38	0.0203		
	50	37	0.0197		
Referenc	e Frequency: LTE E	Band 4 Middle ch	annel=20175 ch	annel=1732.5Ml	-lz
Power supplied	Temperature (°C)	Frequer	Frequency error		Result
(Vdc)	Temperature (0)	Hz	ppm	Limit (ppm)	Result
	-30	31	0.0171	2.5	Pass
	-20	33	0.0185		
	-10	30	0.0164		
	0	27	0.0150		
12.0	10	28	0.0157		
	20	26	0.0143		
	30	40	0.0219		
	40	35	0.0192		
	50	33	0.0185		
Referenc	e Frequency: LTE E	Band 12 Middle c	hannel=23095 c	hannel=707.5Ml	łz
Power supplied (Vdc)	Temperature (°C)	Frequency error		_	Result
	remperature (o)	Hz	ppm		
	-30	54	0.0498	1	
	-20	63	0.0620		
	-10	52	0.0498		
	0	45	0.0395	1	
12.0	10	50	0.0498	2.5 Pas	Pass
	20	43	0.0416		
	30	76	0.0764		
	40	66	0.0641	_	
	50	62	0.0600		



16QAM mode:

Reference	ce Frequency: LTE	Band 2 Middle cl	nannel=18900 cl	nannel=1880MH	z
Power supplied	Tamparatura (90)	Frequency error		Limit (com	D 11
(Vdc)	Temperature (°C)	Hz	ppm	Limit (ppm)	Result
	-30	31	0.0166		
	-20	35	0.0184		
	-10	30	0.0161		
	0	26	0.0137		
12.0	10	29	0.0155	2.5	Pass
	20	26	0.0137		l
	30	39	0.0207		
	40	36	0.0190		
	50	35	0.0184		
Referenc	e Frequency: LTE B	Band 4 Middle ch	annel=20175 ch	annel=1732.5Ml	Ηz
Power supplied	Temperature (°C)	Frequer	cy error	Limit (ppm)	Result
(Vdc)	remperature (C)	Hz	ppm	Еппі (рріп)	
	-30	24	0.0174		Pass
	-20	26	0.0193	2.5	
	-10	23	0.0167		
	0	21	0.0141		
12.0	10	22	0.0161		
	20	20	0.0141		
	30	30	0.0220		
	40	26	0.0200		
	50	26	0.0193		
Referenc	e Frequency: LTE B	and 13 Middle c	hannel=23095 c	hannel=707.5Ml	łz
Power supplied (Vdc)	Temperature (°C)	Frequency error			Result
1 ower supplied (vde)	remperature (C)	Hz	ppm		rtosuit
	-30	52	0.0498		
	-20	60	0.0620		
	-10	50	0.0498		
	0	43	0.0395	_	
12.0	10	48	0.0498	2.5	Pass
	20	42	0.0416]	
	30	73	0.0764]	
	40	63	0.0641]	
	50	60	0.0600		



6.10 Frequency stability V.S. Voltage measurement

Test Requirement:	FCC Part2.1055(d)(1)(2)			
Test Method:	FCC Part2.1055(d)(1)(2)			
Limit:	2.5ppm			
Test setup:	Spectrum analyzer EUT Att. Variable Power Supply			
	Note: Measurement setup for testing on Antenna connector			
Test procedure:	 Set chamber temperature to 25°C. Use a variable DC power source to power the EUT and set the voltage to rated voltage. Set the spectrum analyzer RBW low enough to obtain the desired 			
	frequency resolution and recorded the frequency.			
	3. Reduce the input voltage to specified extreme voltage variation (+/- 15%) and endpoint, record the maximum frequency change.			
Test Instruments:	Refer to section 6.0 for details			
Test mode:	Refer to section 6.1 for details			
Test results:	Pass			



Measurement Data QPSK mode:

QFSK IIIoue.					
Referen	ce Frequency: LTE	Band 2 Middle cl	nannel=18900 ch	annel=1880MH	z
Temperature (°C)	Power supplied (Vdc)	Frequency error		Limit (nnm)	Dogult
		Hz	ppm	Limit (ppm)	Result
	13.20	18	0.0094	2.5	Pass
25	12.00	20	0.0105		
	10.80	22	0.0116		
Reference Frequency: LTE Band 4 Middle channel=20175 channel=1732.5MHz					
Temperature (°C)	Power supplied	Frequency error		Limit (nnm)	Result
Temperature (°C)	(Vdc)	Hz	ppm	- Limit (ppm)	Result
25	13.20	24	0.0137		
	12.00	15	0.0088	2.5	Pass
	10.80	18	0.0104	1	
Reference	e Frequency: LTE E	Band 12 Middle c	hannel=23095 cl	nannel=707.5Mb	łz
Temperature (°C)	Power supplied	Frequency error		Limit (ppm)	Result
	(Vdc)	Hz	ppm	Limit (ppin)	Nesuit
25	13.20	20	0.0282		
	12.00	28	0.0392	2.5	Pass
	10.80	28	0.0392		



16QAM mode:

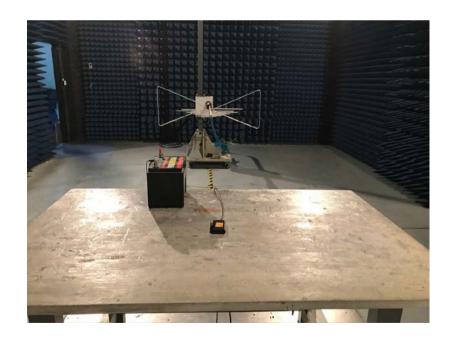
Reference Frequency: LTE Band 2 Middle channel=18900 channel=1880MHz					
Temperature (°C)	Power supplied (Vdc)	Frequency error		Limit (ppm)	Result
		Hz	ppm	Ellilli (ppill)	Nesuit
	13.20	19	0.0100		
25	12.00	21	0.0112	2.5	Pass
	10.80	23	0.0124		
Reference Frequency: LTE Band 4 Middle channel=20175 channel=1732.5MHz					
Temperature (°C)	Power supplied	Frequency error		Limit (ppm)	Result
remperature (0)	(Vdc)	Hz	ppm	- Limit (ppin)	Nesuit
	13.20	23	0.0130		
25	12.00	15	0.0084	2.5	Pass
	10.80	17	0.0099		
Reference Frequency: LTE Band 13 Middle channel=23095 channel=707.5MHz					
Temperature (°C)	Power supplied	Frequency error		Limit (ppm)	Result
remperature (C)	(Vdc)	Hz	ppm	Еппі (рріп)	Nesult
	13.20	19	0.0264		
25	12.00	26	0.0366	2.5	Pass
	10.80	26	0.0366		



7 Test Setup Photo

Radiated Emission





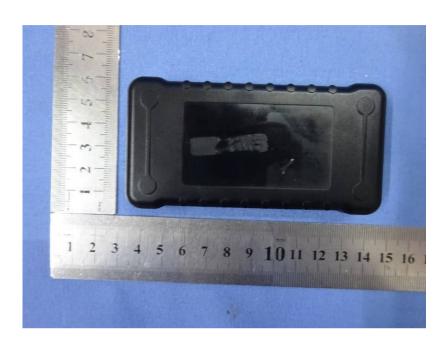


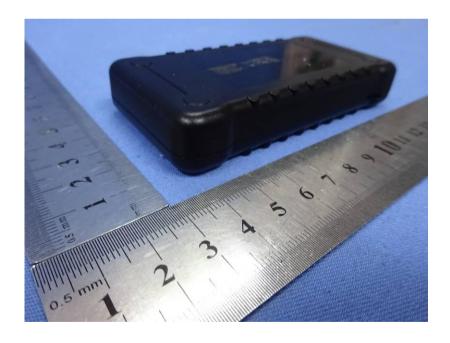
8 EUT Constructional Details









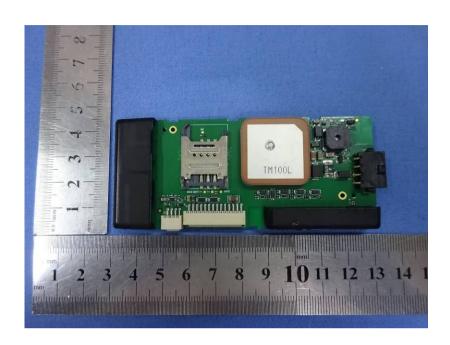


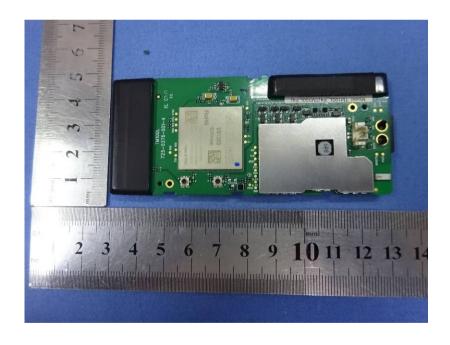




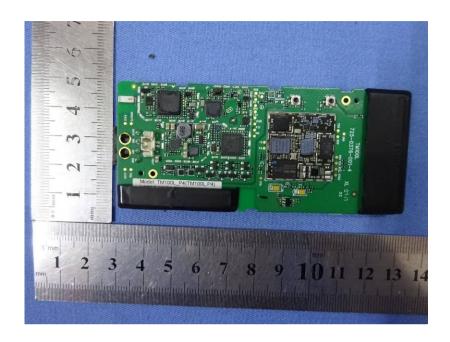


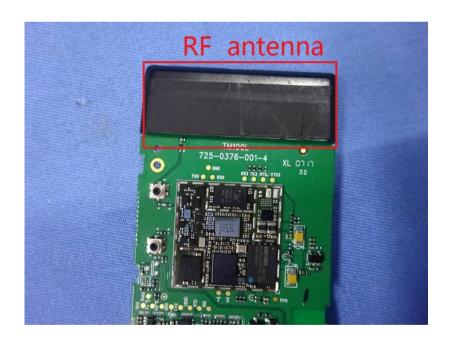












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